

Barrier Properties of TCOs against Metallization and Interconnection materials for Thermal Stability of Perovskite Solar Cells

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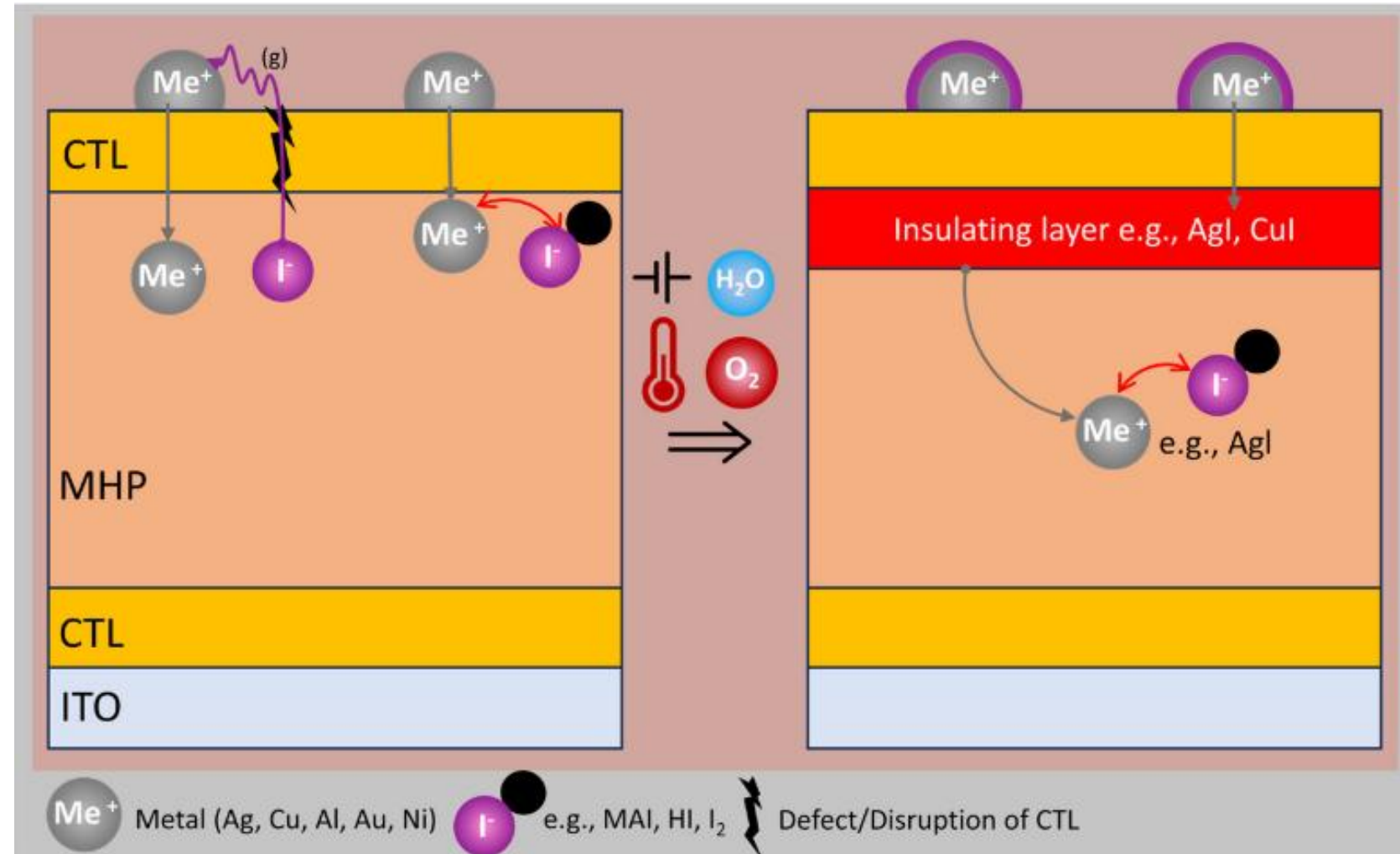
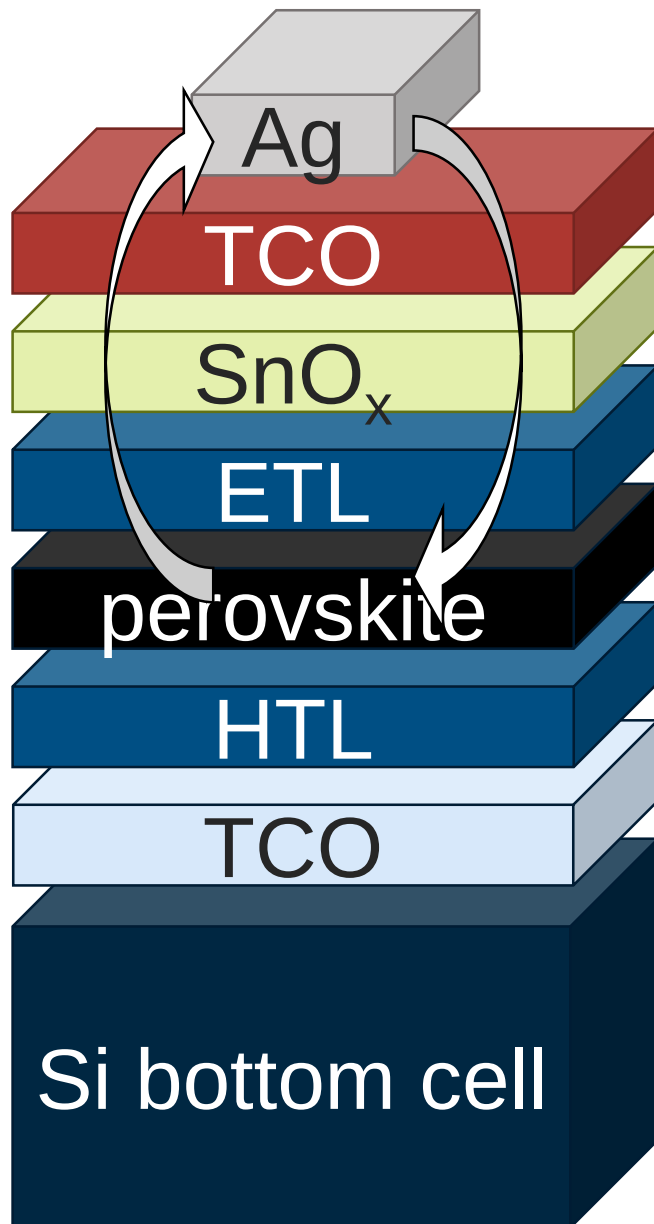
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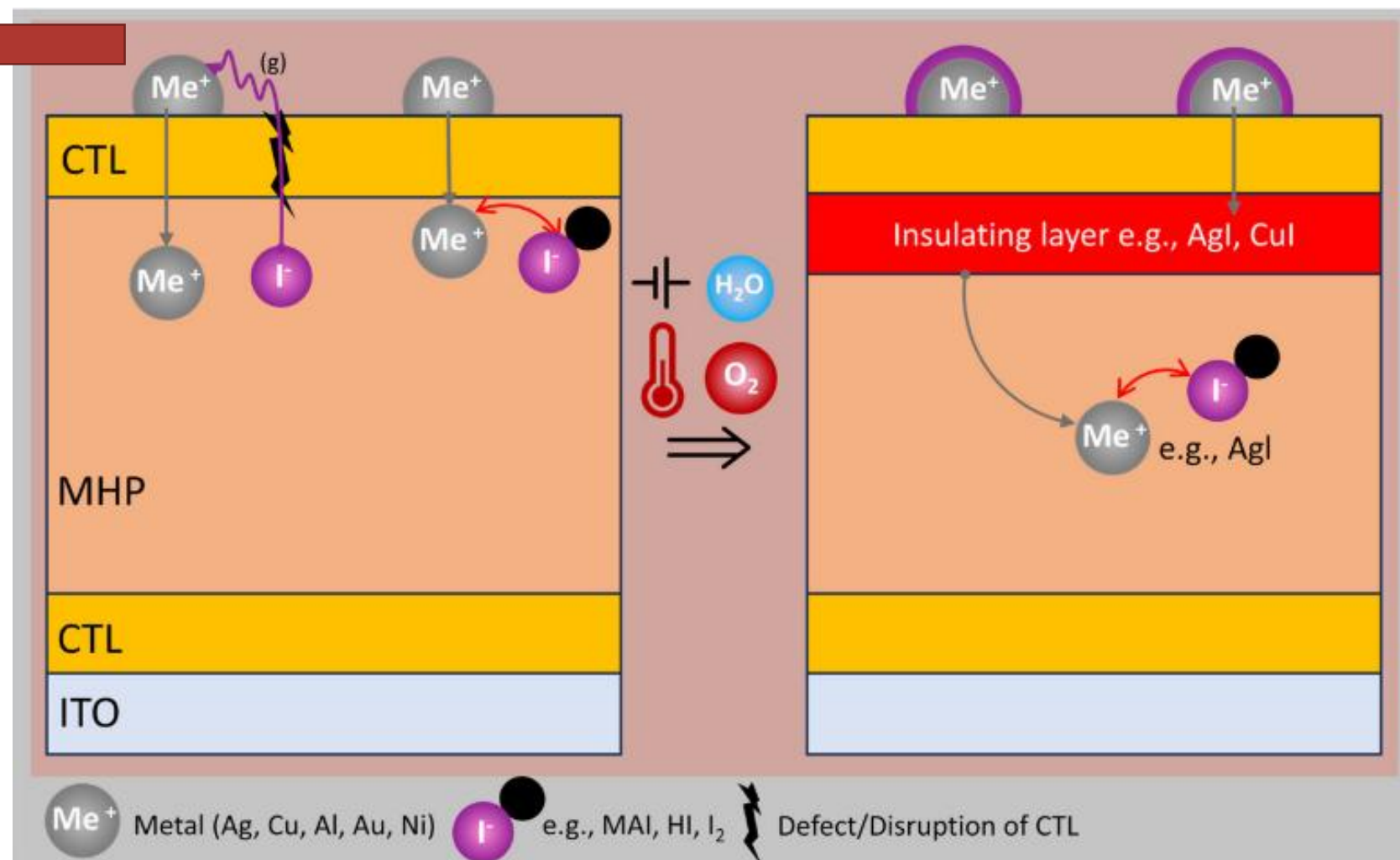
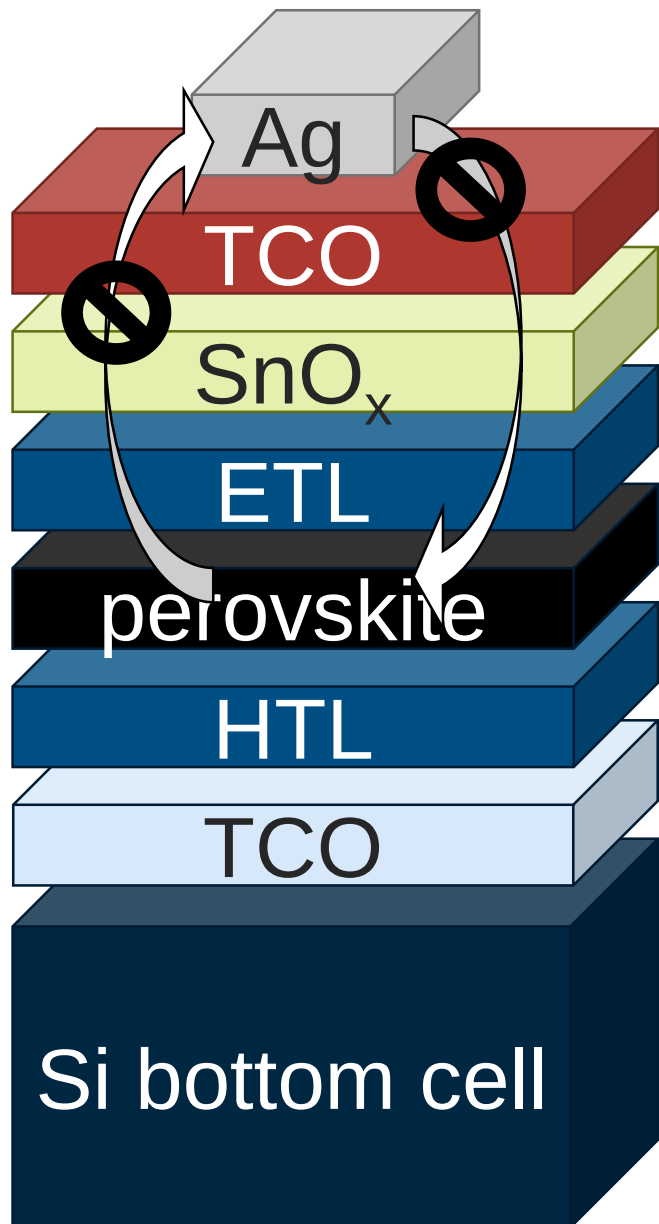
³Oxford PV



MOTIVATION



MOTIVATION





Investigate how **degradation** related to **sp-Ag** can be reduced by optimisation of **top-contact TCO**.

1. Test TCOs in unencapsulated **in-house 1 cm² single-junction perovskite** solar cells.
2. Test TCOs in encapsulated **industrial M6 silicon/perovskite tandem** solar cells.

1. Test TCOs in unencapsulated in-house 1 cm² single-junction perovskite solar cells.



EXPERIMENT DESIGN

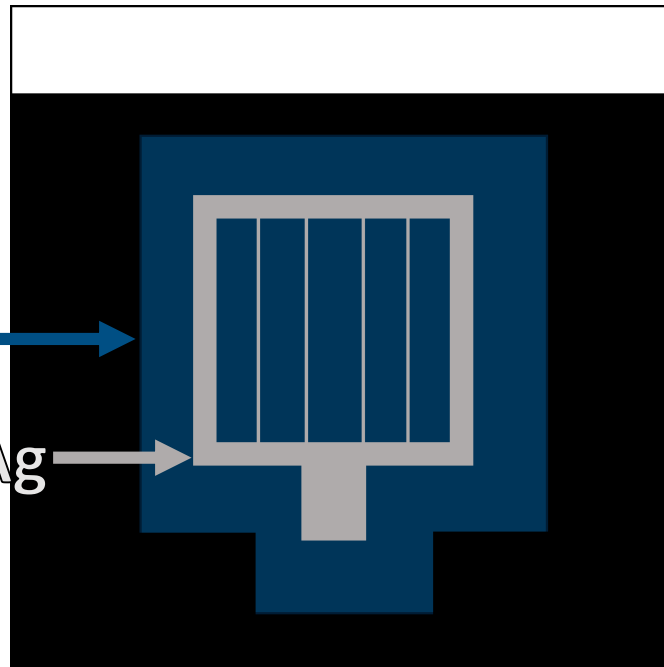
Dr. Philippe Holzhey



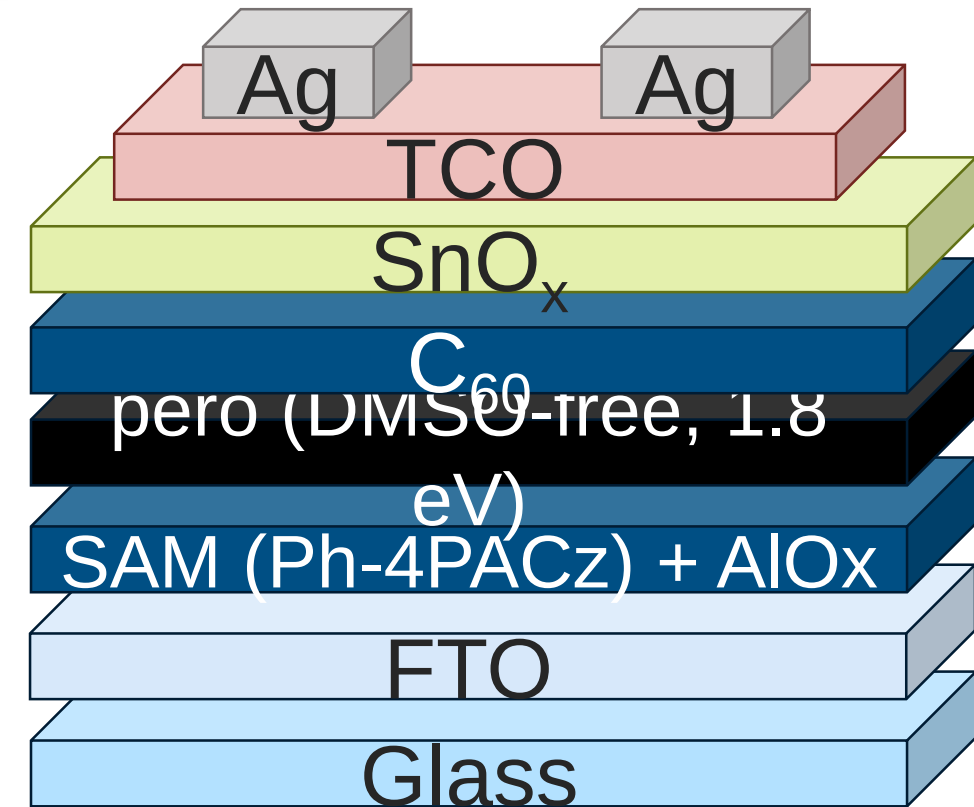
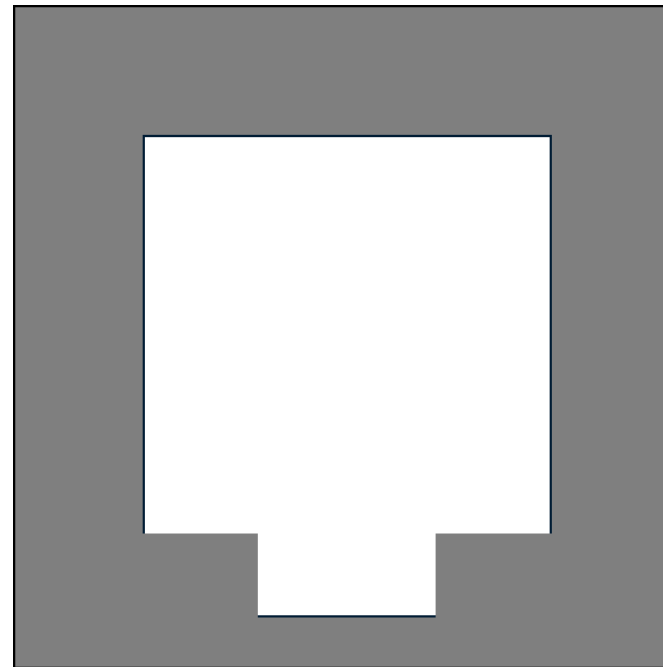
Objective:

Test barrier properties of TCOs against **sp-Ag**

1 cm² device



TCO mask design

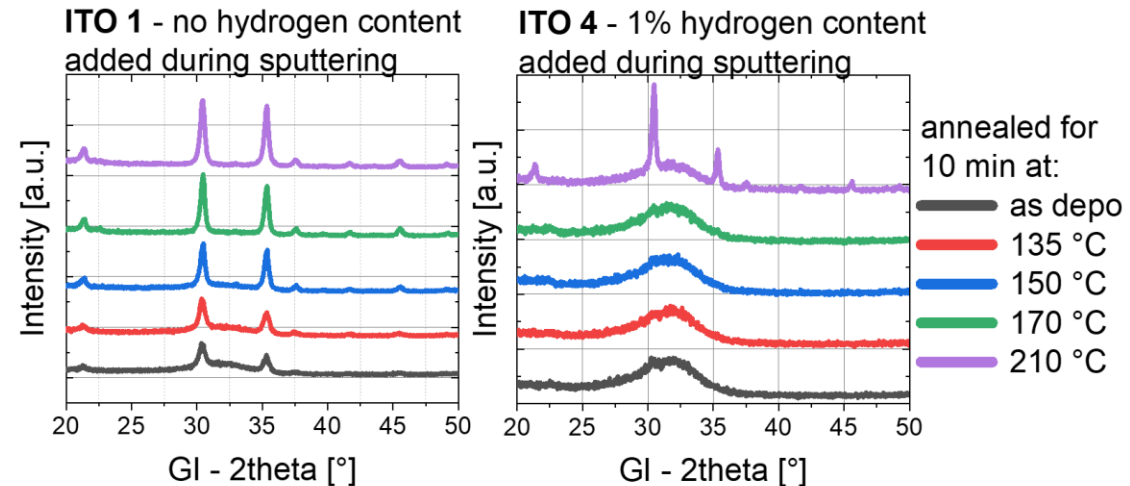




	TCO	Thickness
1	IZO 5 μbar	40 nm
2	IZO 14 μbar	
3	a-ITO	
4	c-ITO	

- ITO $\rightarrow$ industry standard
- IZO $\rightarrow$ silicon-perovskite community standard
- Low-T ITO developed at HZB
- Crystallinity varied, no performance reduction

XRD-results



EXPERIMENT DESIGN

Jannik Kleesiek

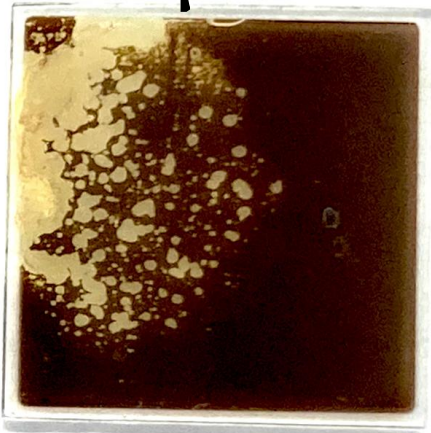
Poster B-03



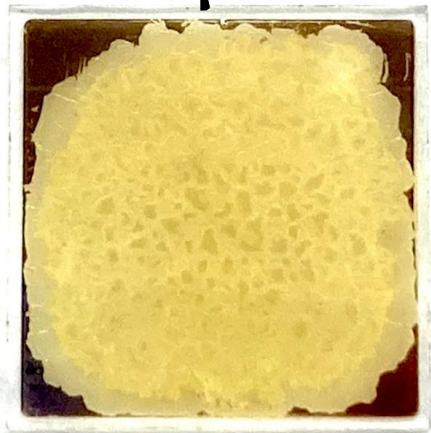
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- ITO $\rightarrow$ industry standard
- IZO $\rightarrow$ silicon-perovskite community standard
- Low-T ITO developed at HZB
- Crystallinity varied, no performance reduction
- IZO: sputter pressure varied
- High pressure $\rightarrow$ poor barrier

5 μ bar



14 μ bar



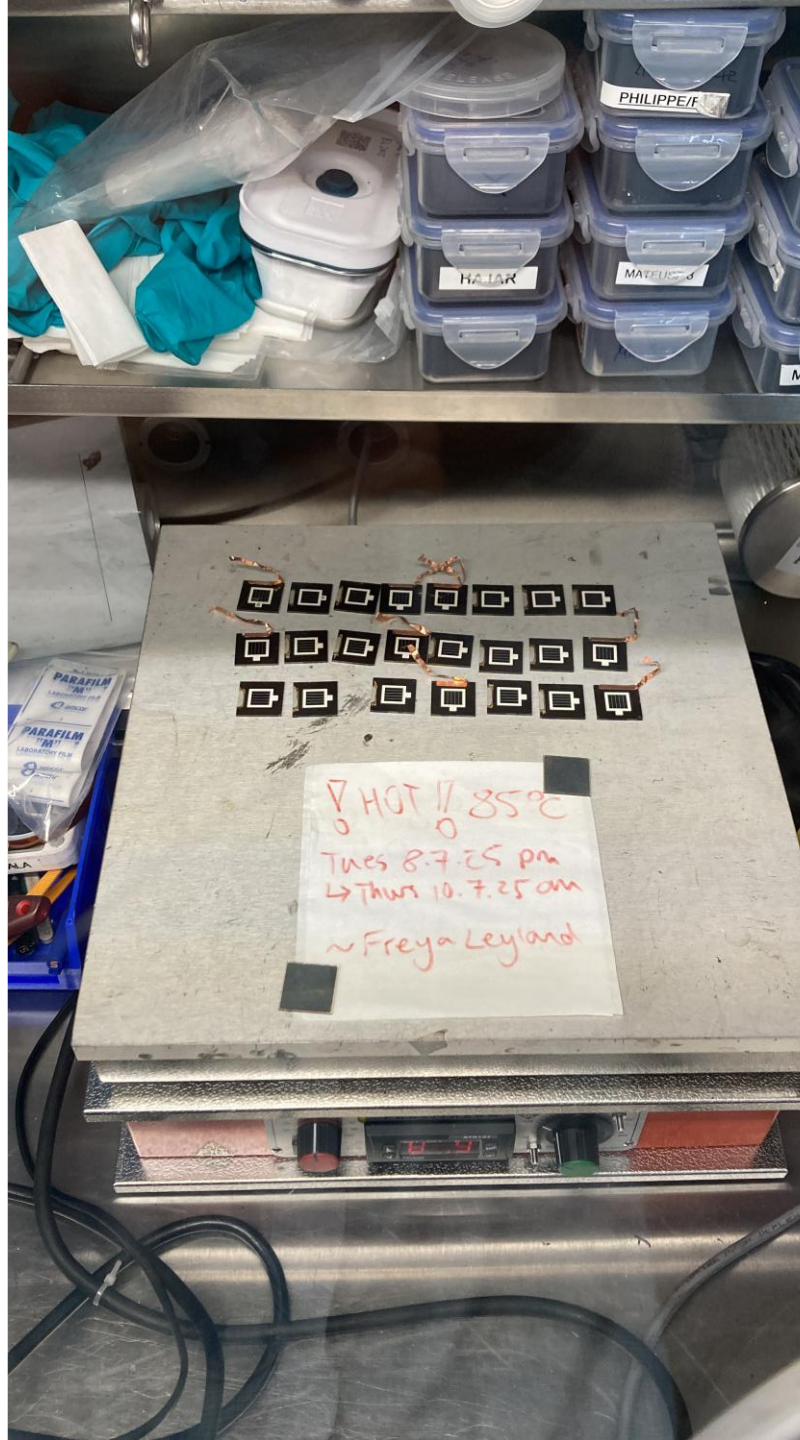
EXPERIMENT DESIGN

	TCO	Thickness
1	IZO 5 μ bar	40 nm
2	IZO 14 μ bar	
3	a-ITO	
4	c-ITO	
5	IZO 5 μ bar	100 nm
6	a-ITO	
7	c-ITO	

- Thickness varied
- Thicker $\rightarrow$ better barrier
- Trade off with reduced transparency

EXPERIMENT DESIGN

	TCO	Thickness
1	IZO 5 μbar	40 nm
2	IZO 14 μbar	
3	a-ITO	
4	c-ITO	
5	IZO 5 μbar	100 nm
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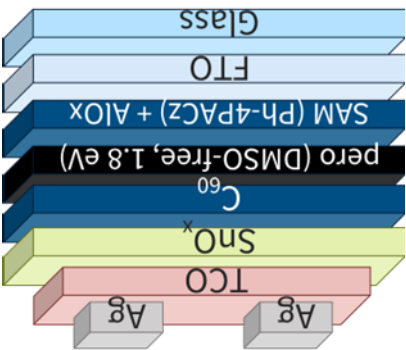
Ageing:

- 85 °C
- Hotplate
- Glovebox - N₂ atmosphere
- Dark(ish)
- **41 hours**

PHOTOGRAPHS FROM BACKSIDE

Aged at 85 °C, dark

From rear side through glass

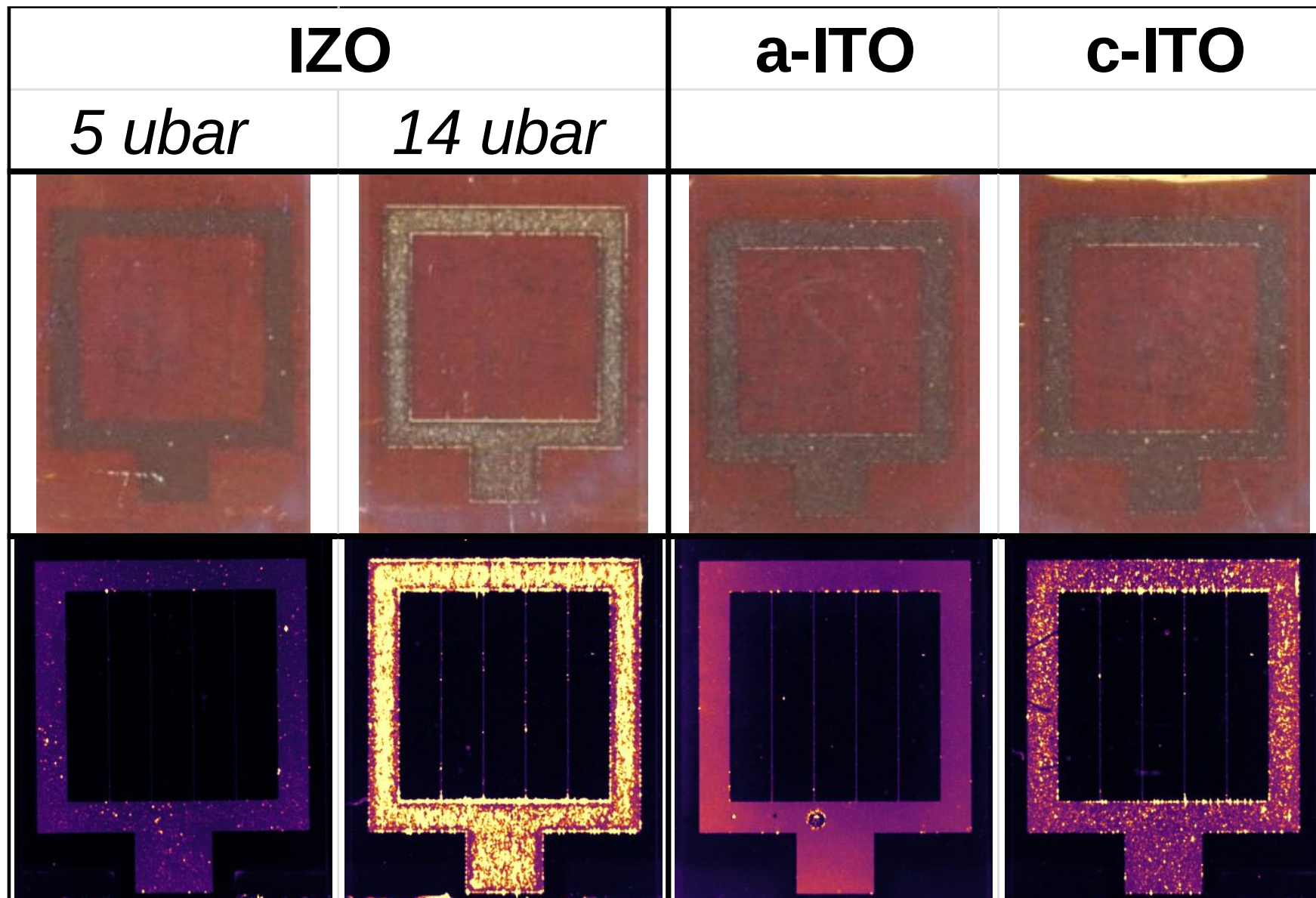
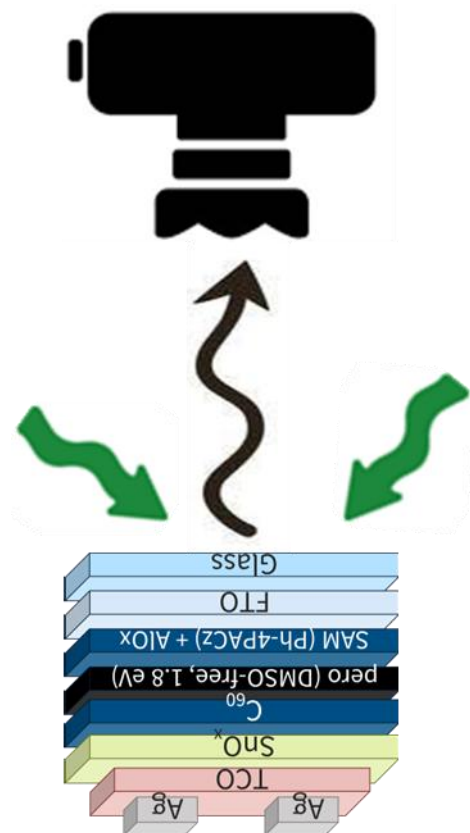


IZO		a-ITO	c-ITO
5 ubar	14 ubar		

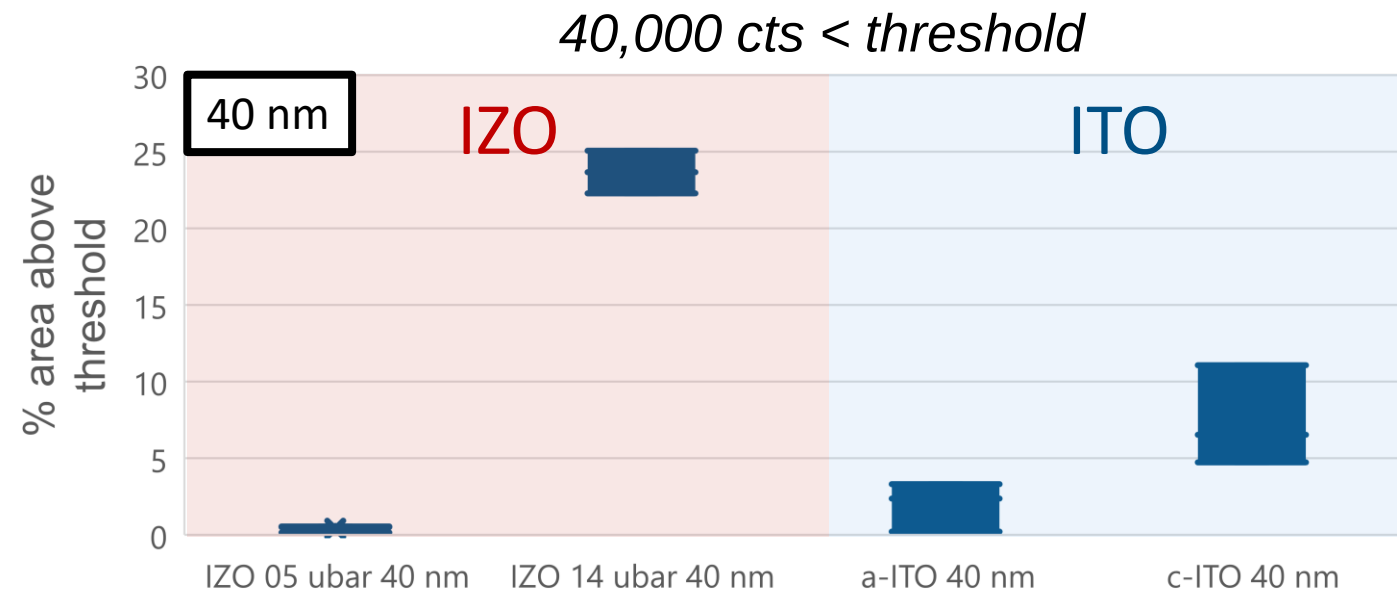
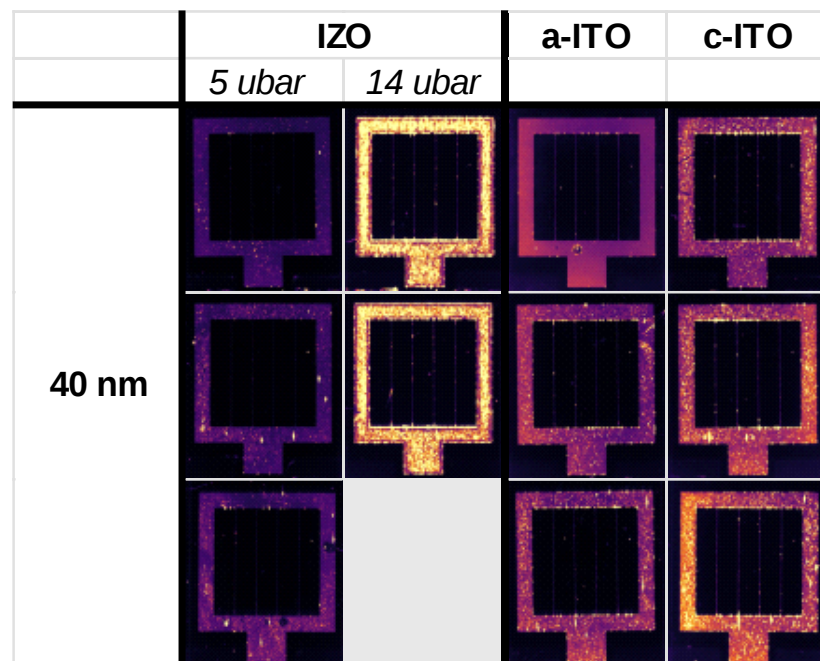
PL FROM BACKSIDE

Aged at 85 °C, dark

From rear side through glass

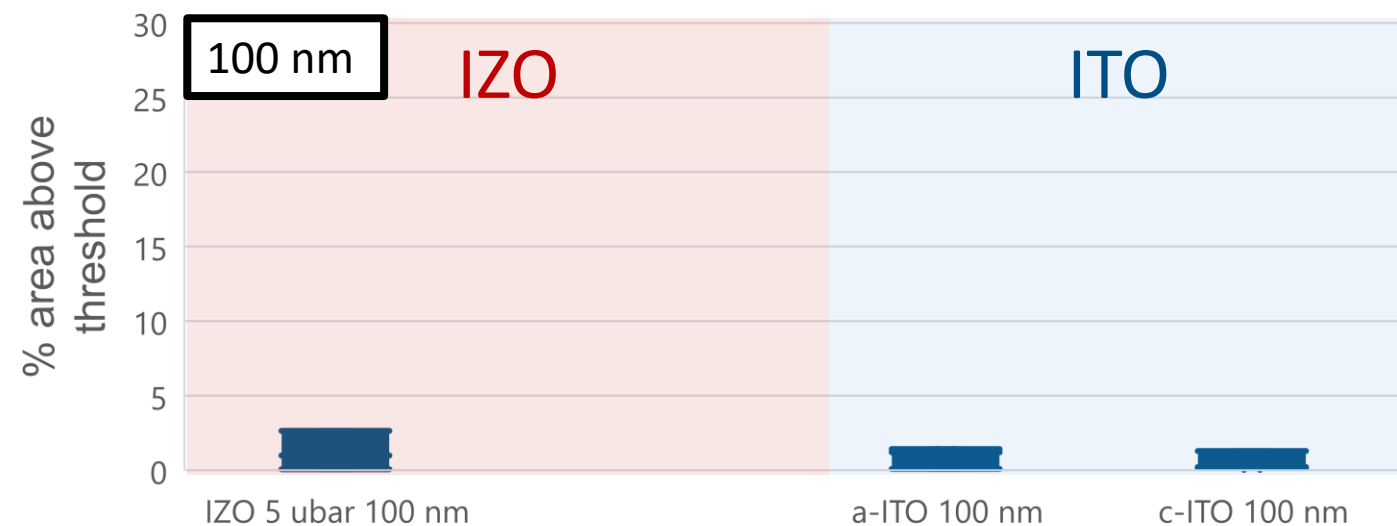
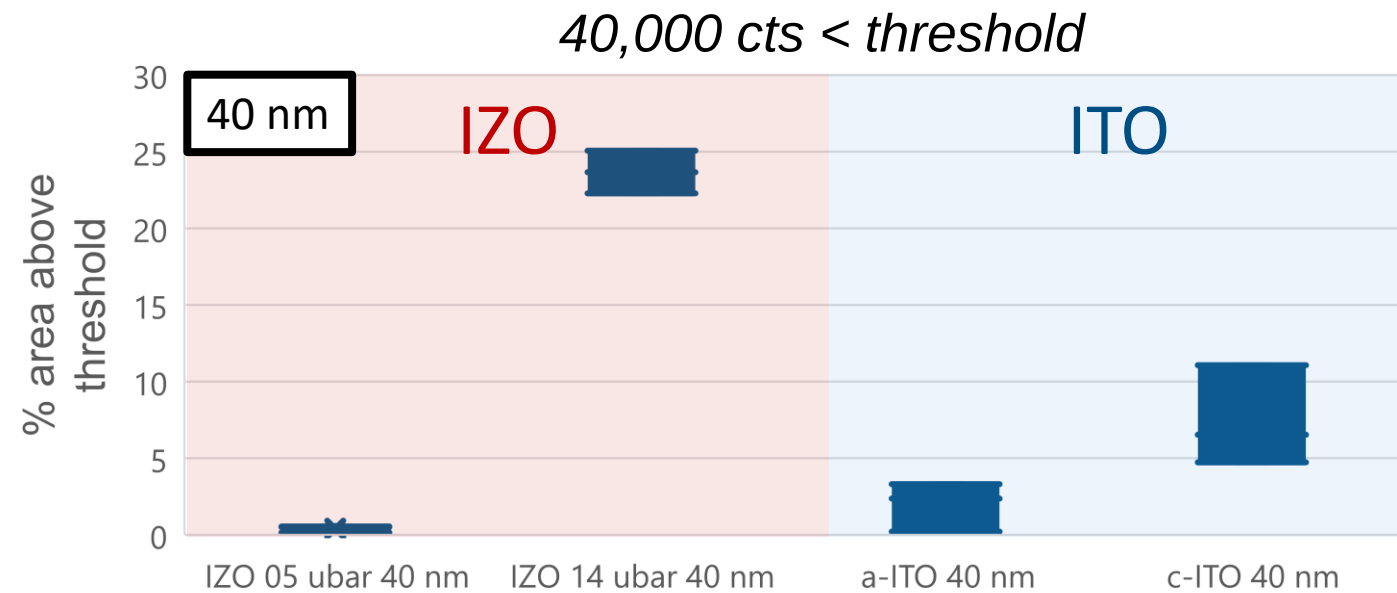
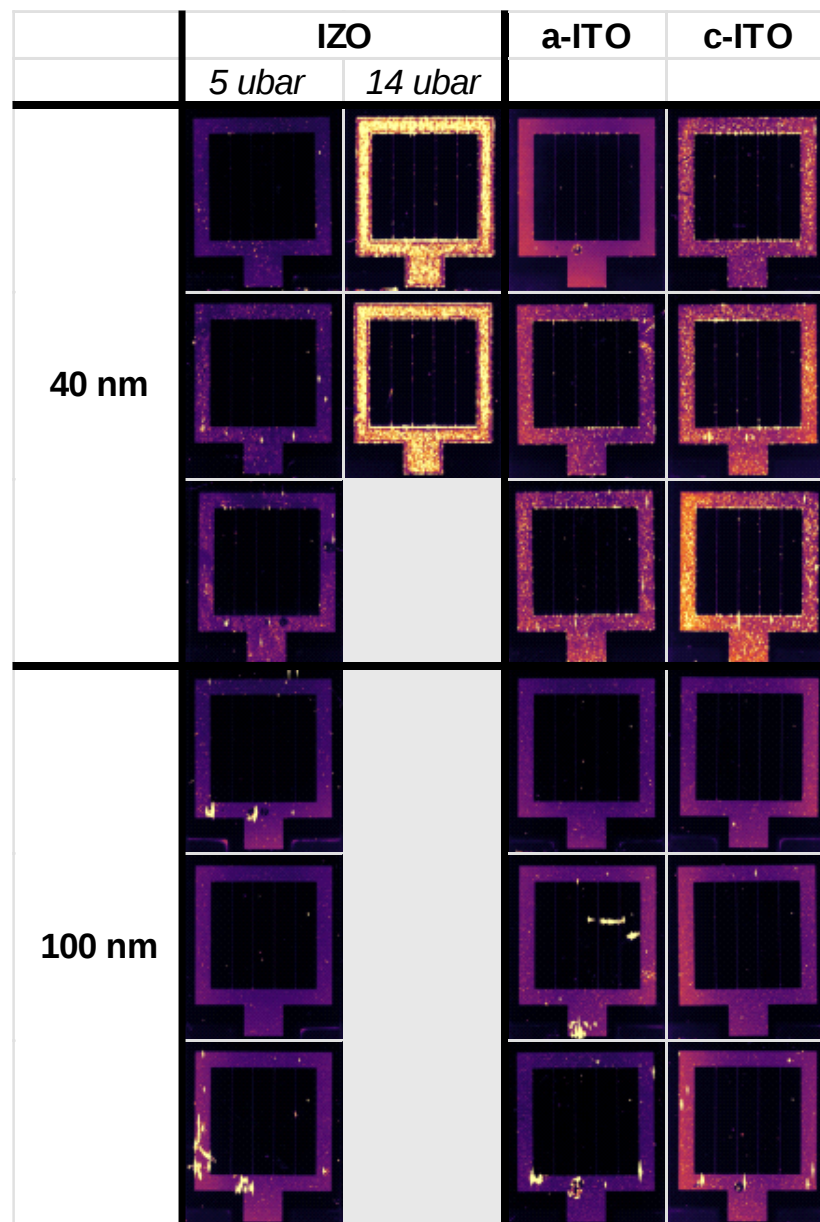


PL FROM BACKSIDE



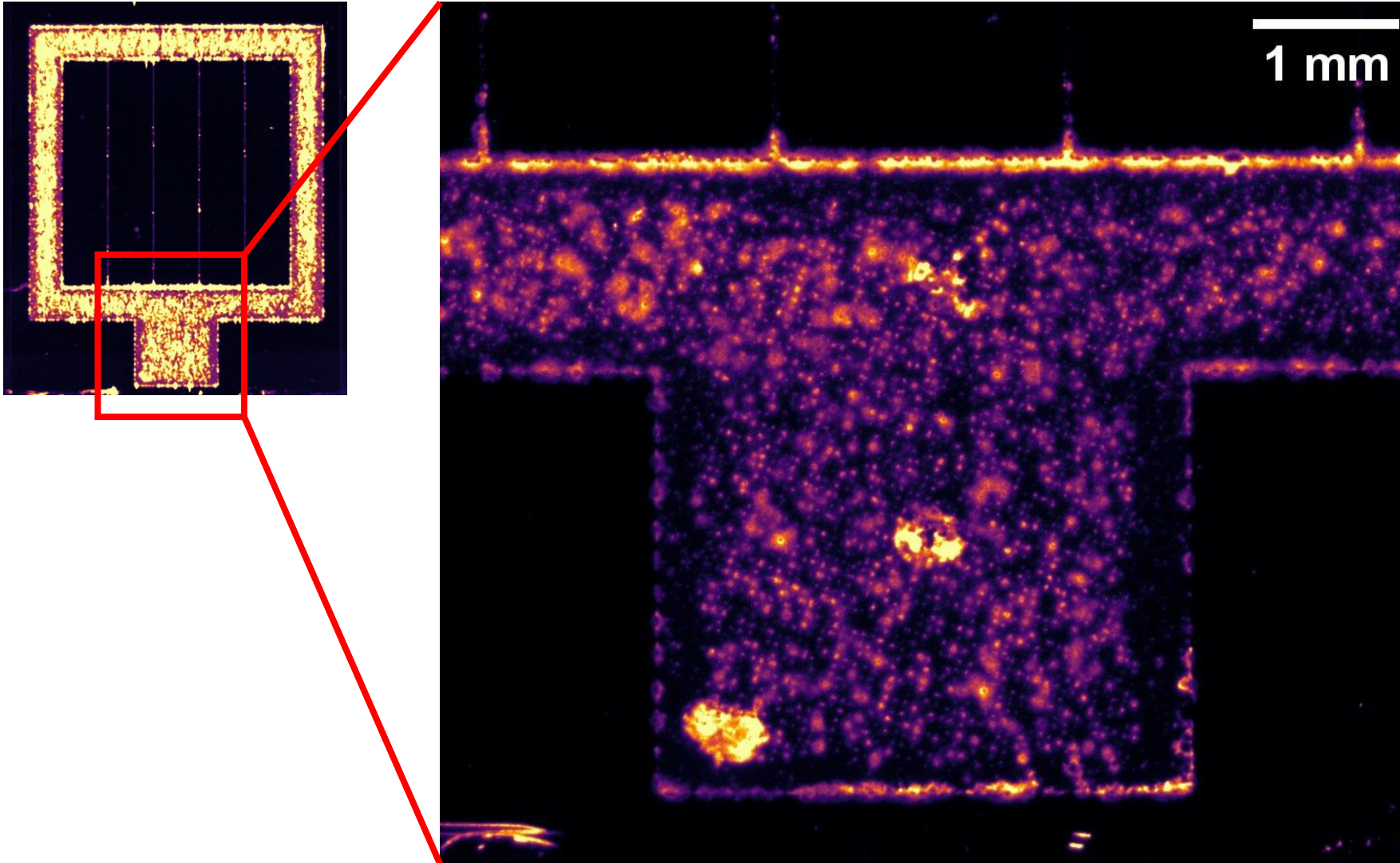
- IZO 5 μ bar > a-ITO > c-ITO > IZO 14 μ bar

PL FROM BACKSIDE



- IZO 5 μ bar > a-ITO > c-ITO > IZO 14 μ bar
- Increasing thickness improves barrier

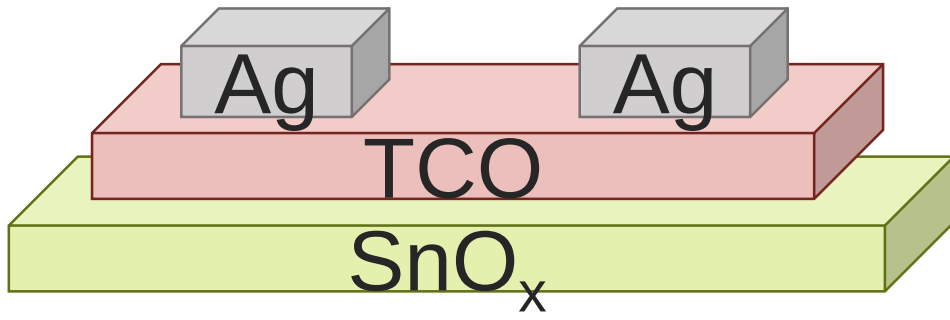
SCREEN-PRINTING GRID MESH



- Grid observed
- Spacing = **0.7 μm**
- Screen printing mesh grid spacing = **0.7 μm**
- Pressure points allow Ag diffusion.

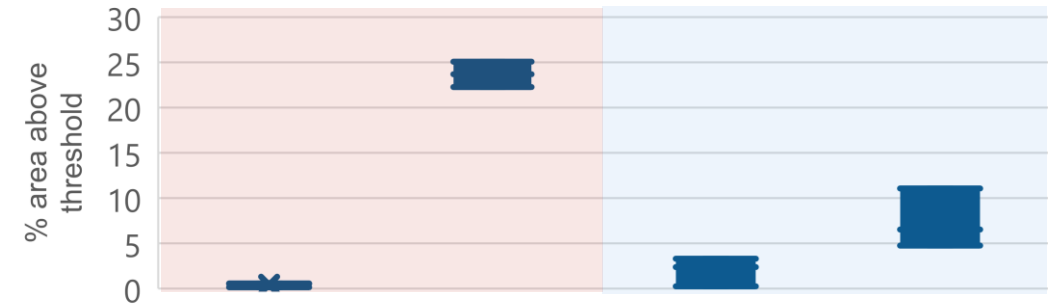
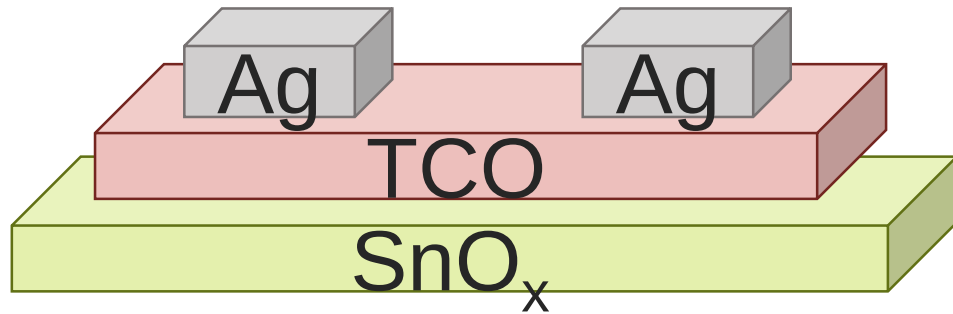


XPS – SILVER INGRESS TO C60 INTERFACE

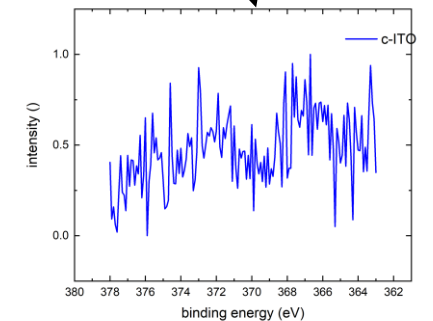
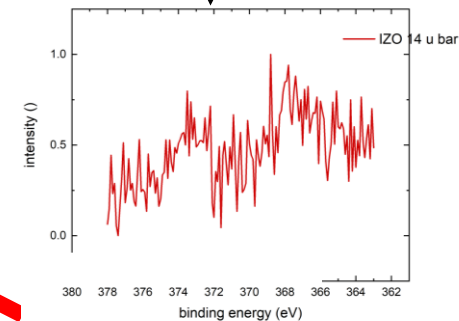
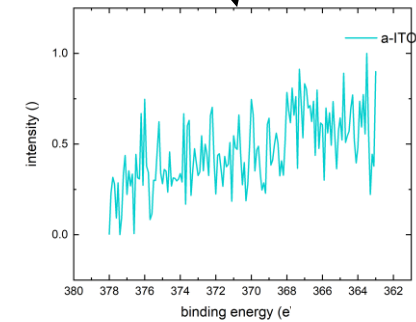
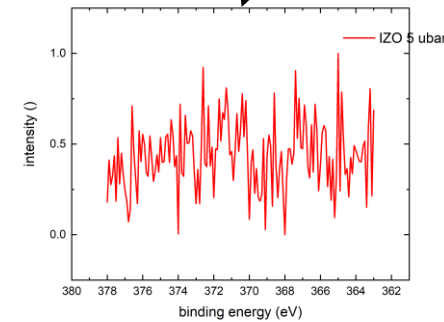




XPS – SILVER INGRESS TO C60 INTERFACE

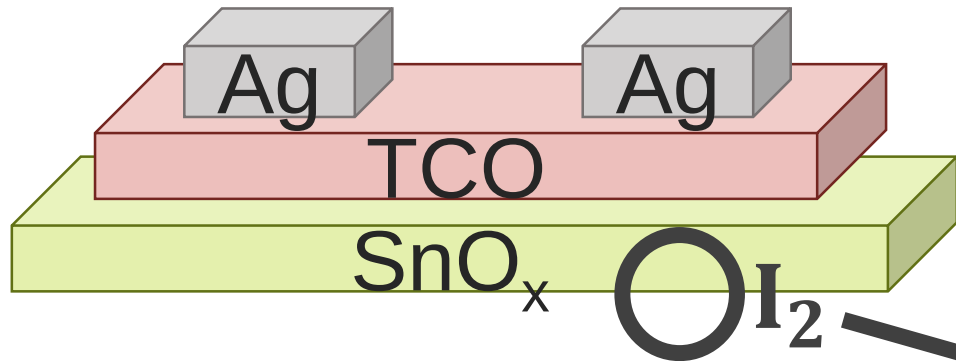


	IZO 5 μ bar	IZO 14 μ bar	a-ITO	c-ITO
Ag detected?	X	✓	X	✓

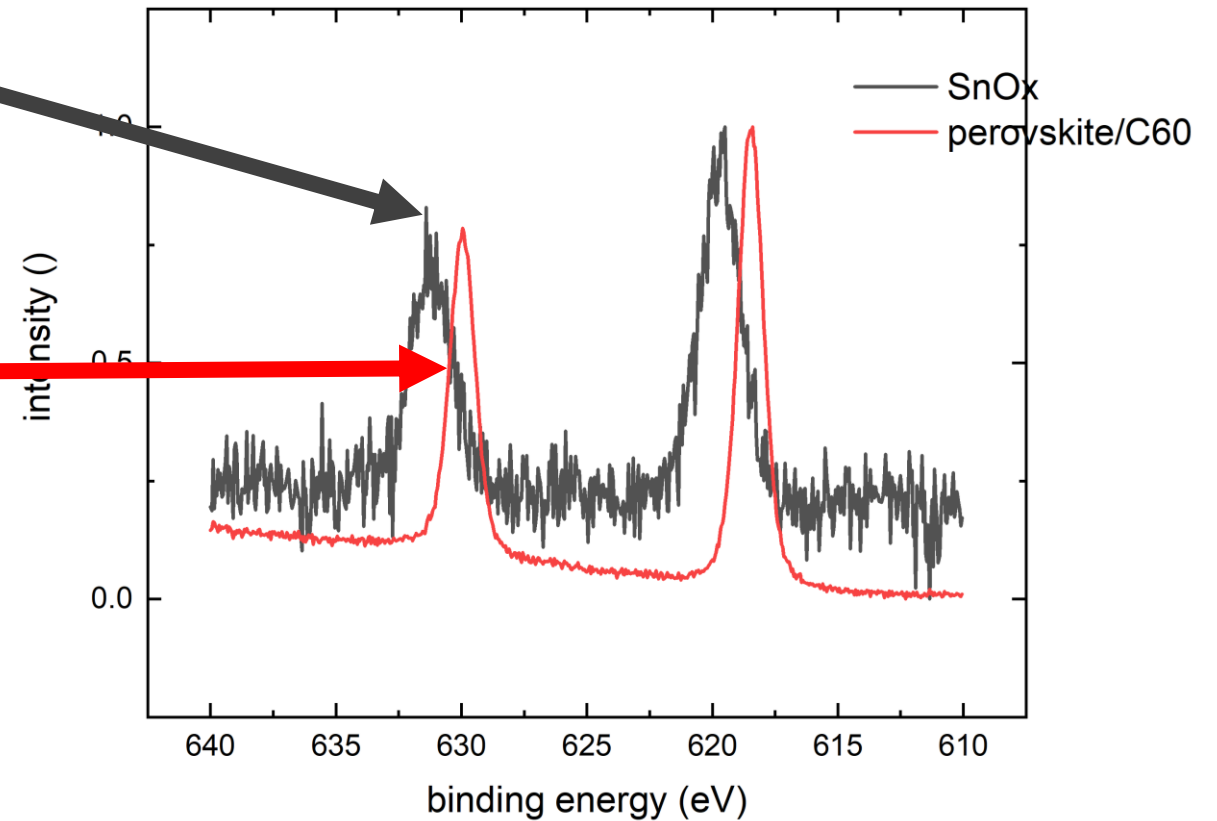
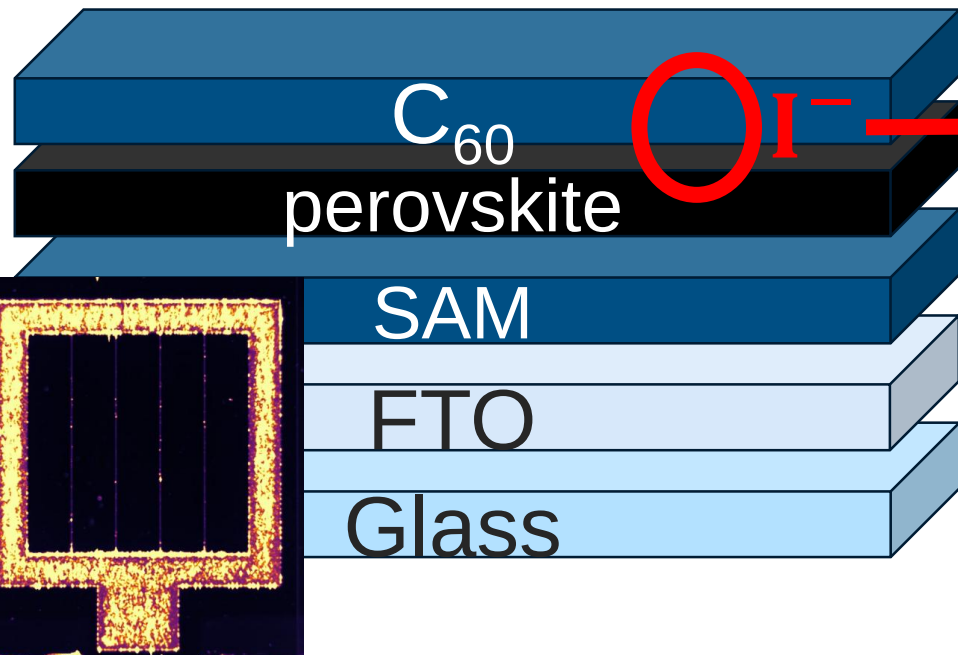




XPS – IODINE BONDING ENVIRONMENT



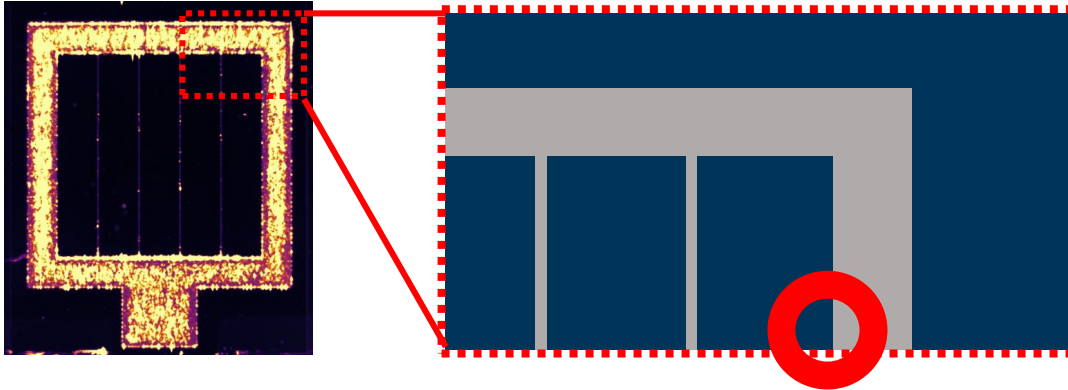
- Iodine 3d peak shifted by 1.5 eV depending on location indicates different bonding environments.
- I₂ diffuses from perovskite up towards Ag contacts.



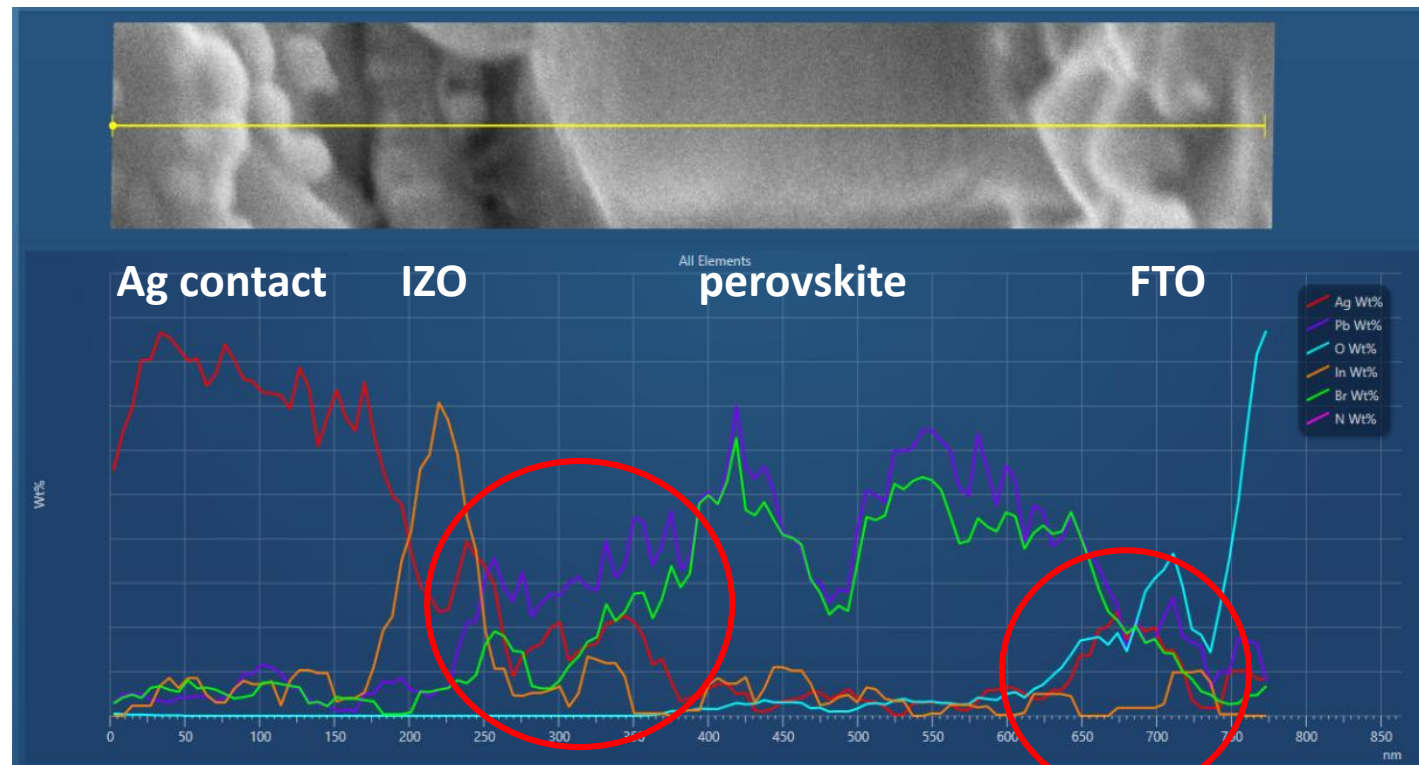


CROSS-SECTION SEM-EDX

14 μ bar IZO (high pressure, poor barrier)



- Ag diffusion
- Accumulation at FTO surface – Ag⁰ plating?
- Accumulation at perovskite/C60 interface – AgI?

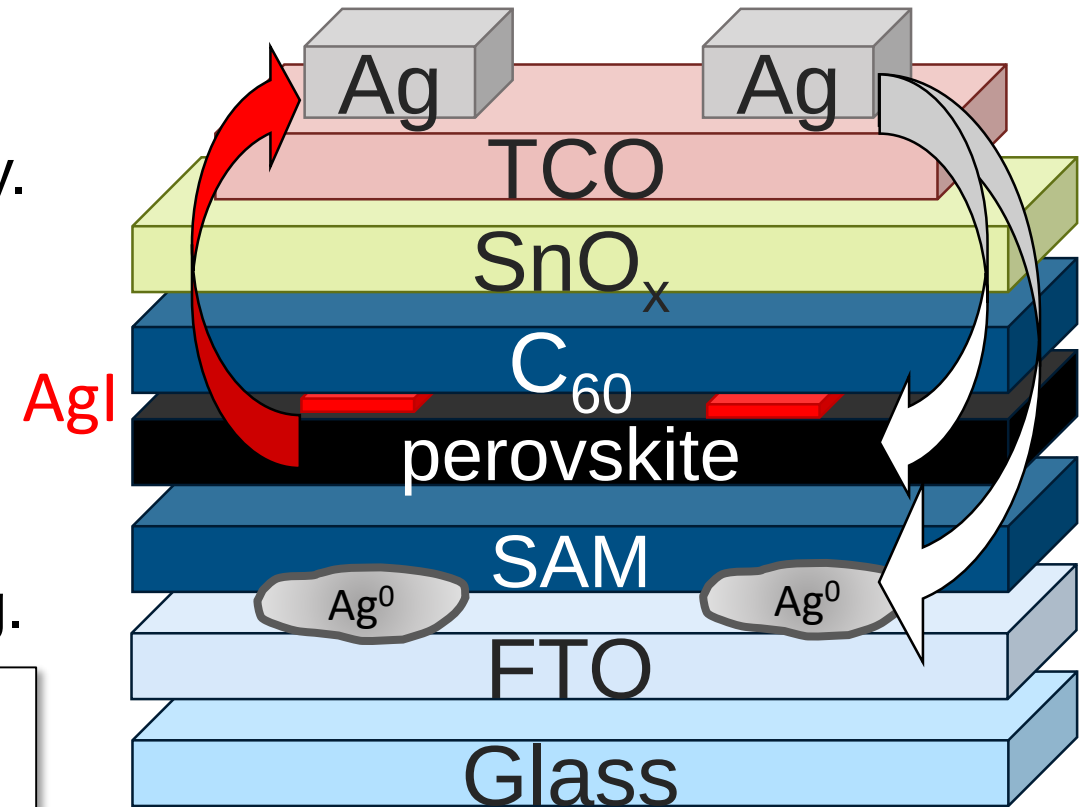


CONCLUSIONS

- IZO ($5 \mu\text{bar}$) > a-ITO > c-ITO > IZO ($15 \mu\text{bar}$).
- Increasing thickness improves barrier quality.
- Silver diffuses down and iodine diffuses up.
- Silver accumulates at perovskite and FTO surfaces.
- Speculative: formation of AgI and Ag^0 plating.

Outlook:

- Directly measure Ag^0 at FTO surface.
- Understand why TCOs have differing barrier properties.



2. Test TCOs in encapsulated industrial M6 silicon/perovskite tandem solar cells.



WORKFLOW

Key: Oxford PV

HZB

Tandem fabrication

TCO

Metallisation
ECA interconnection
Encapsulation

Characterisation

Aging

85 °C, dark,
ambient, 1000 h

Characterisation



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WORKFLOW

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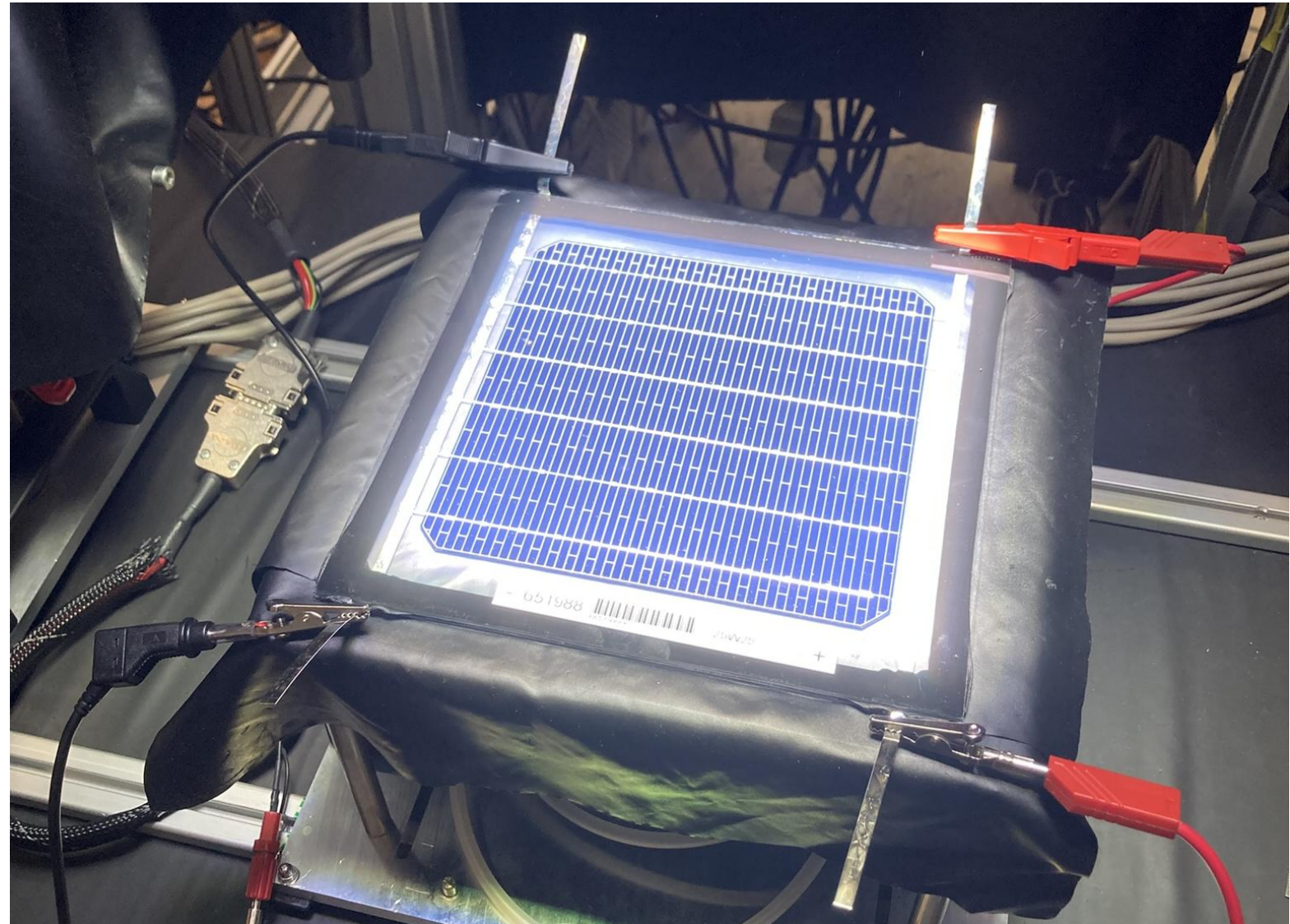
Characterisation

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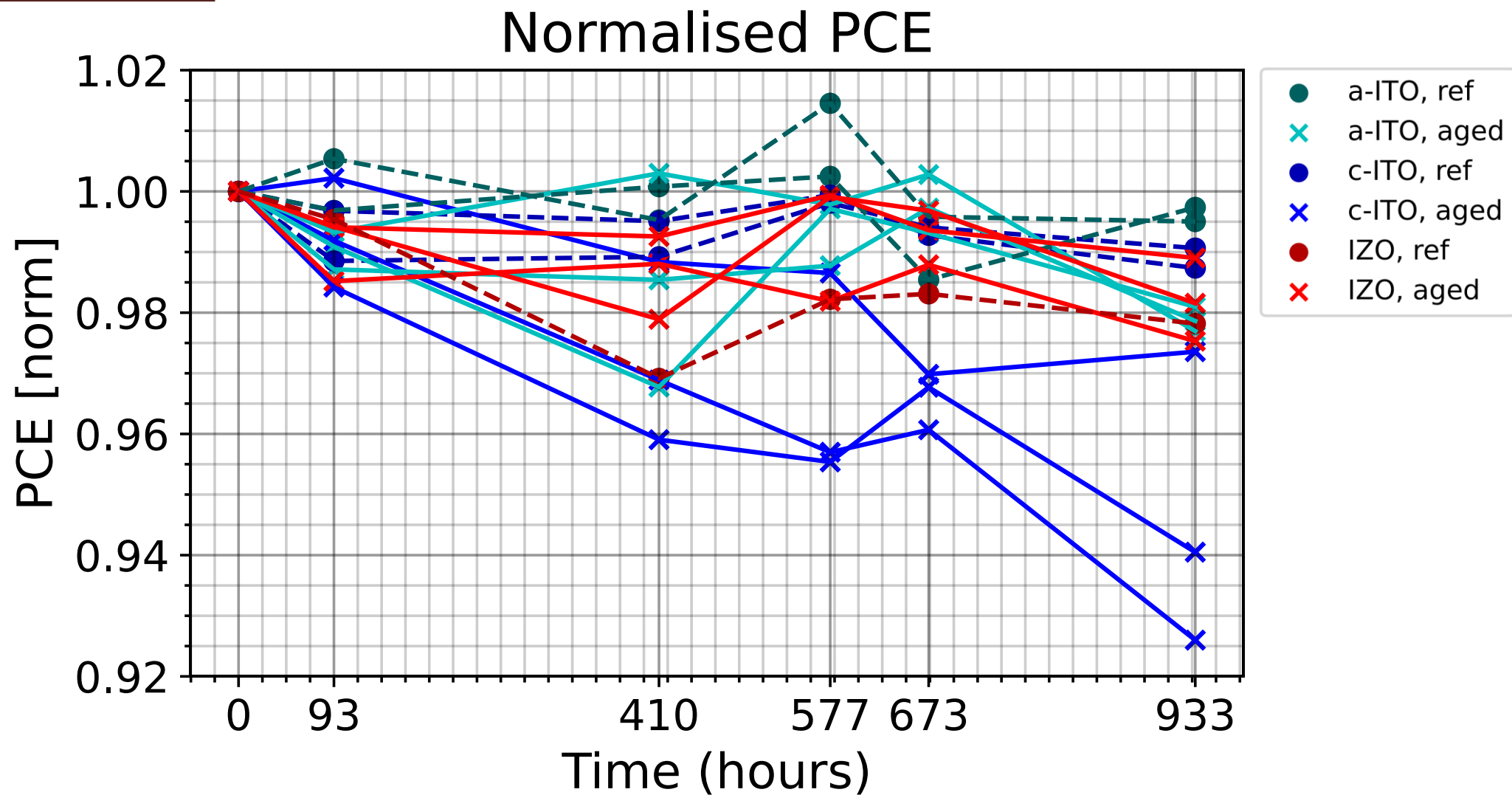


Characterisation



JV – PCE

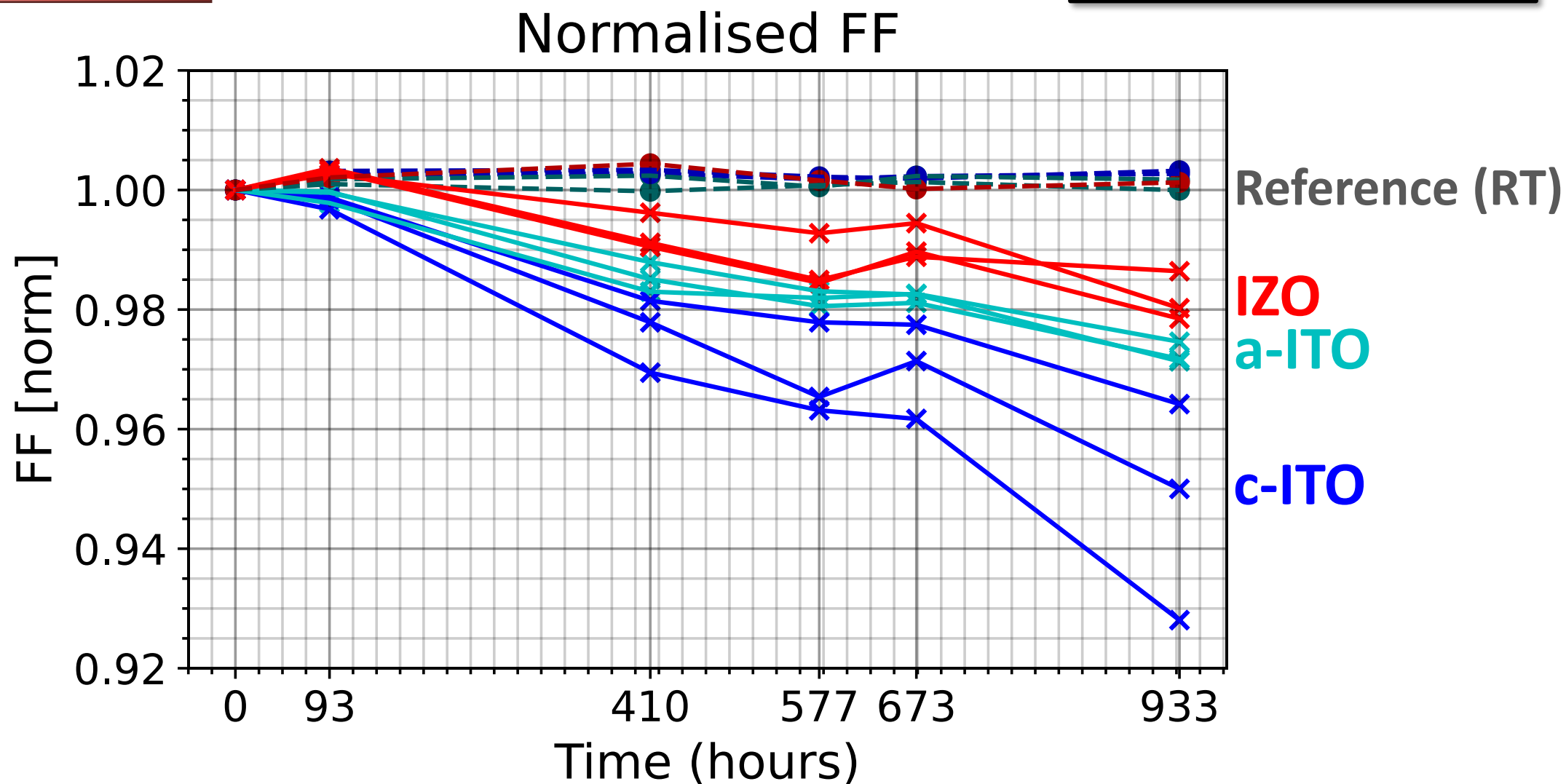
Aged at 85 °C, dark



JV – FF

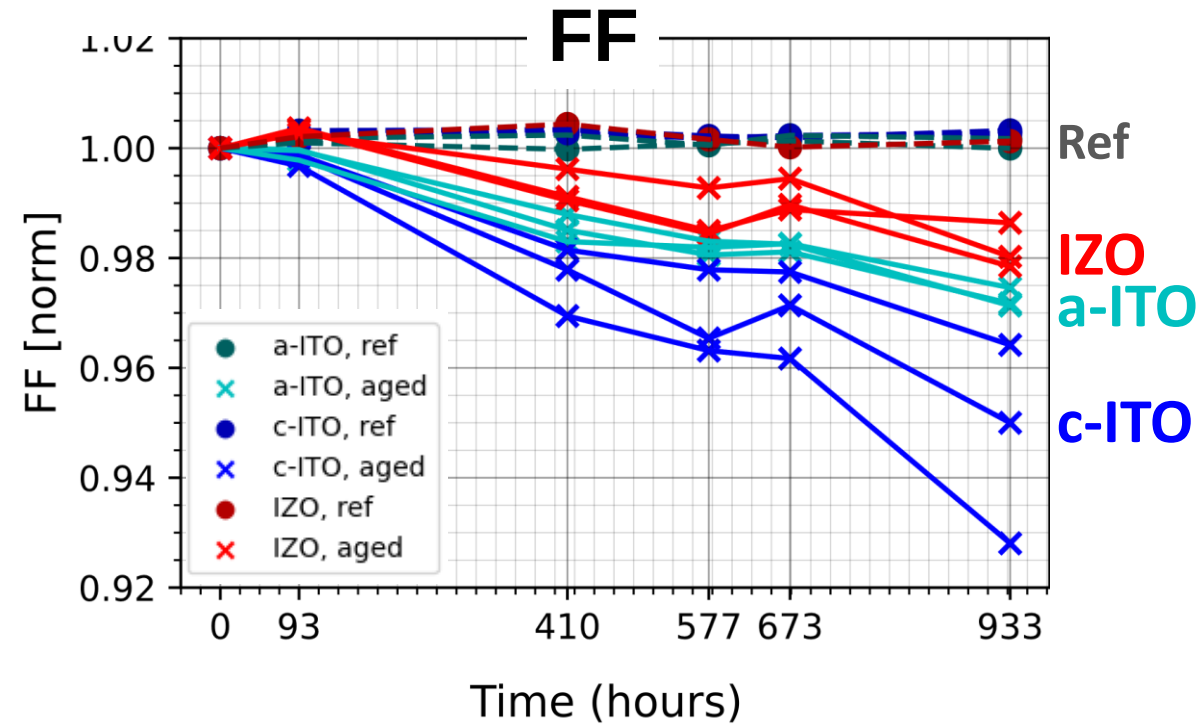
Aged at 85 °C, dark

IZO > a-ITO > c-ITO

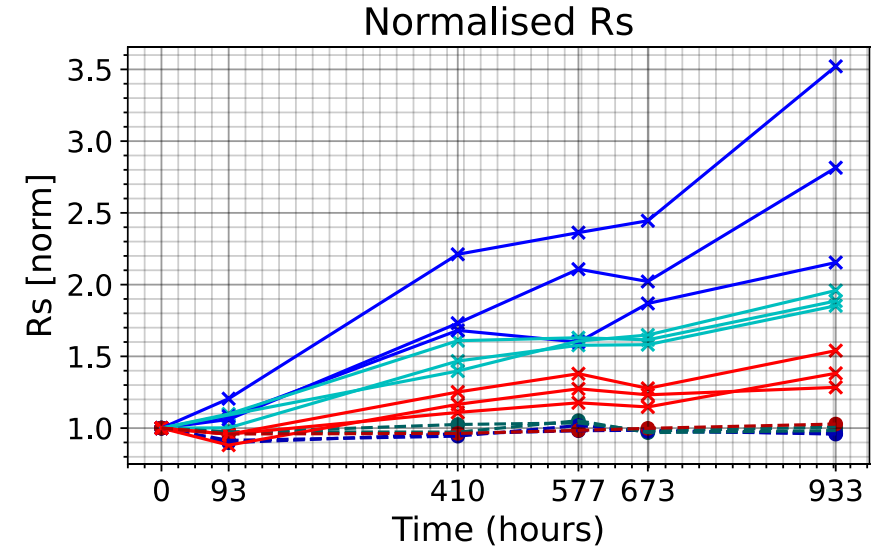
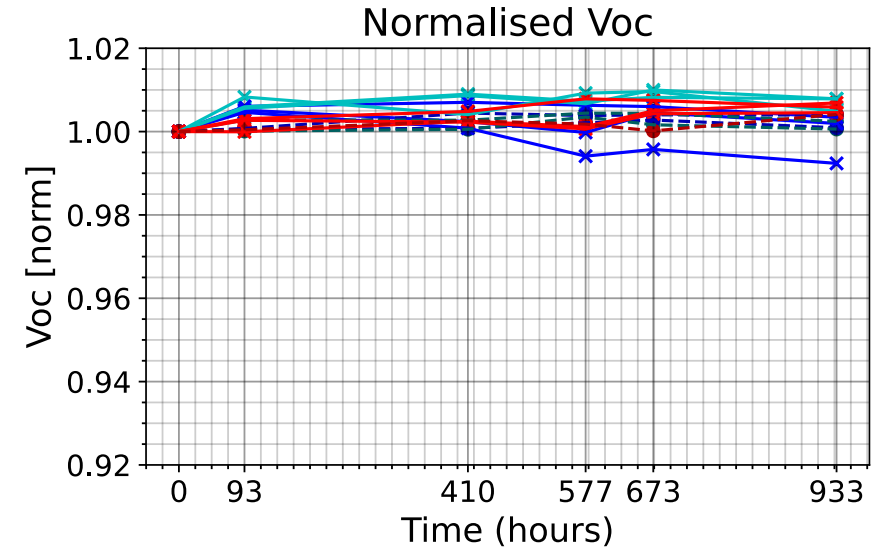


RS AND VOC

Aged at 85 °C, dark

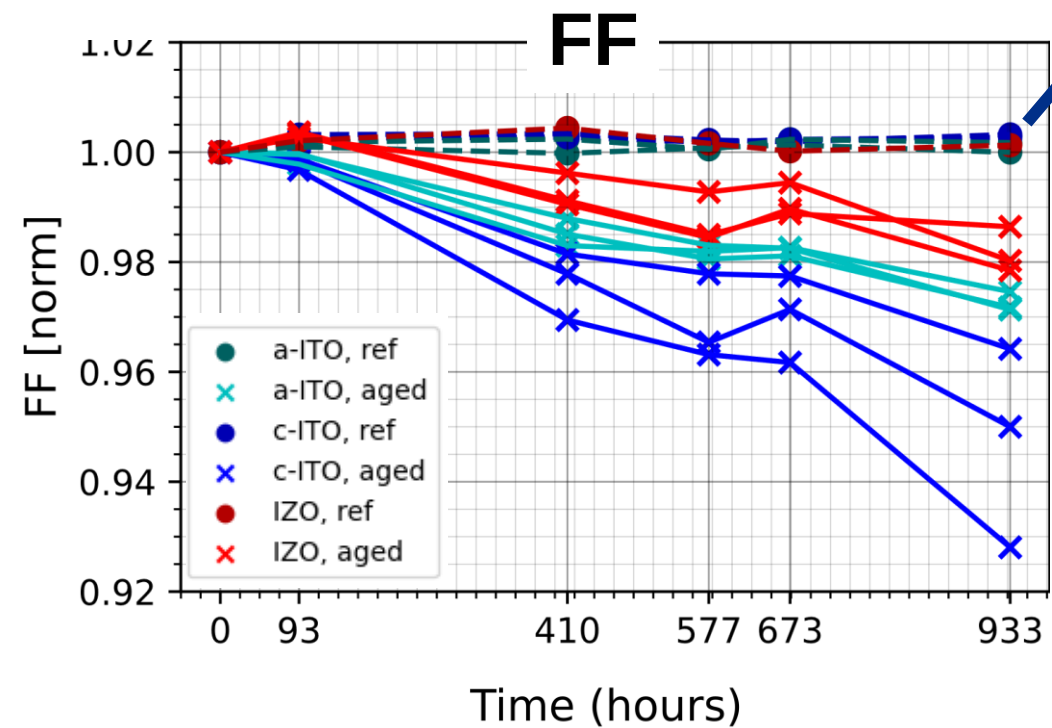


- No change in Voc
- Increased $R_s \rightarrow$ drop in FF
- Degradation due to metal corrosion



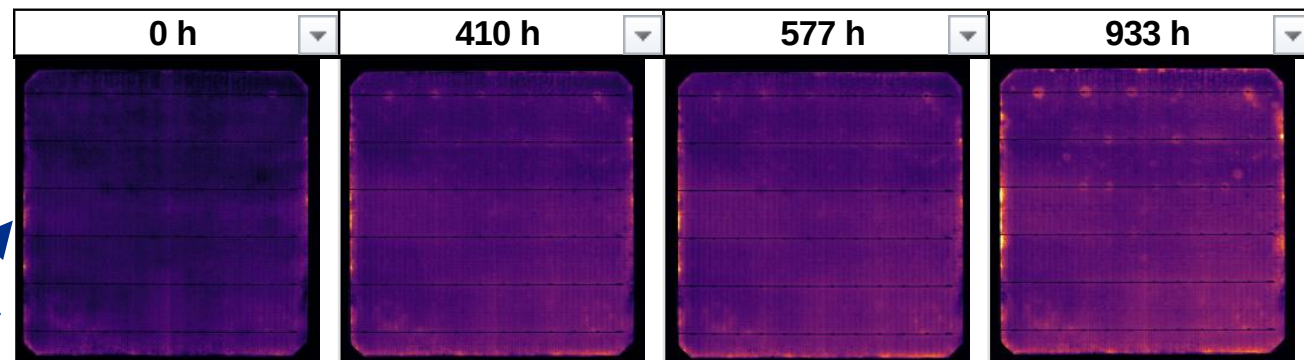
EL IMAGING

Aged at 85 °C, dark



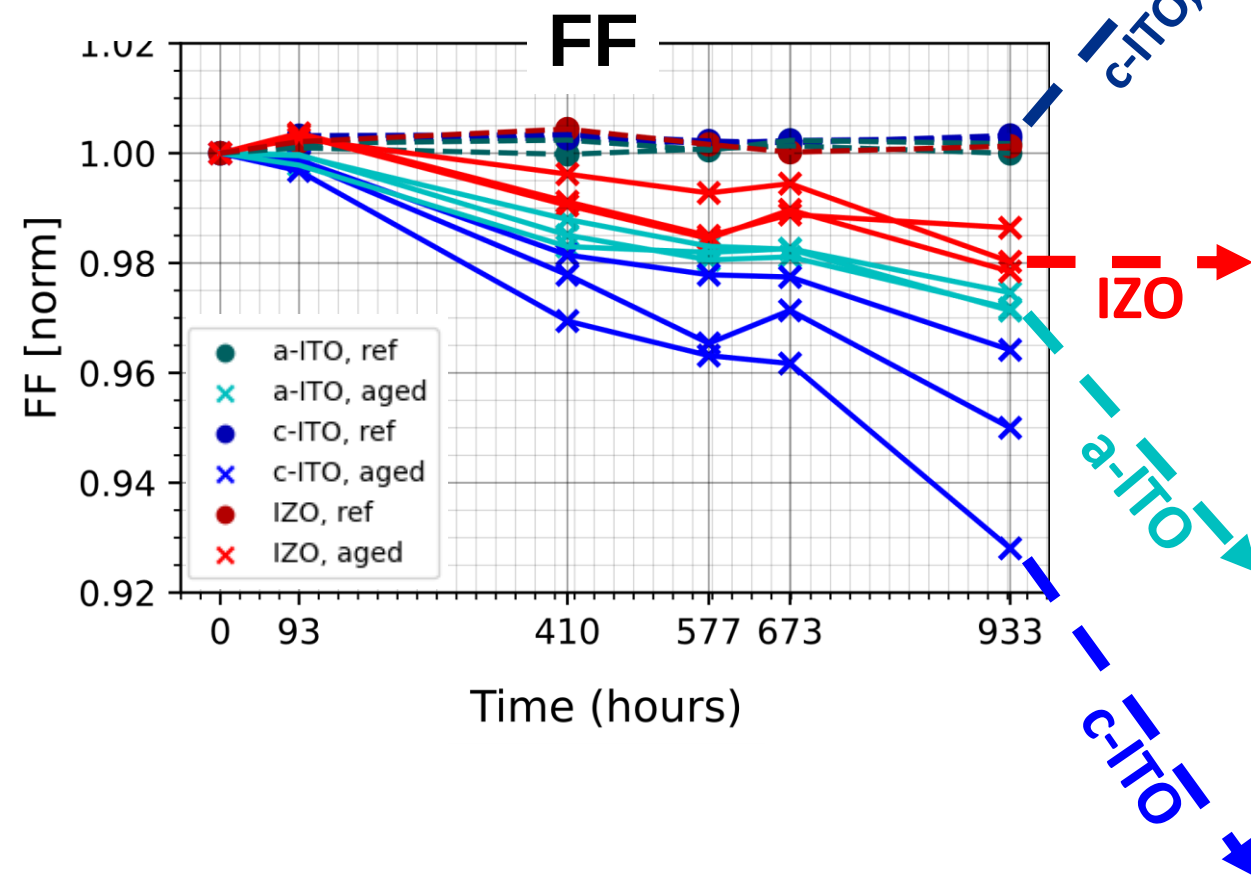
c-ITO, ref

64826
48634
32442
16249
57



EL IMAGING

Aged at 85 °C, dark



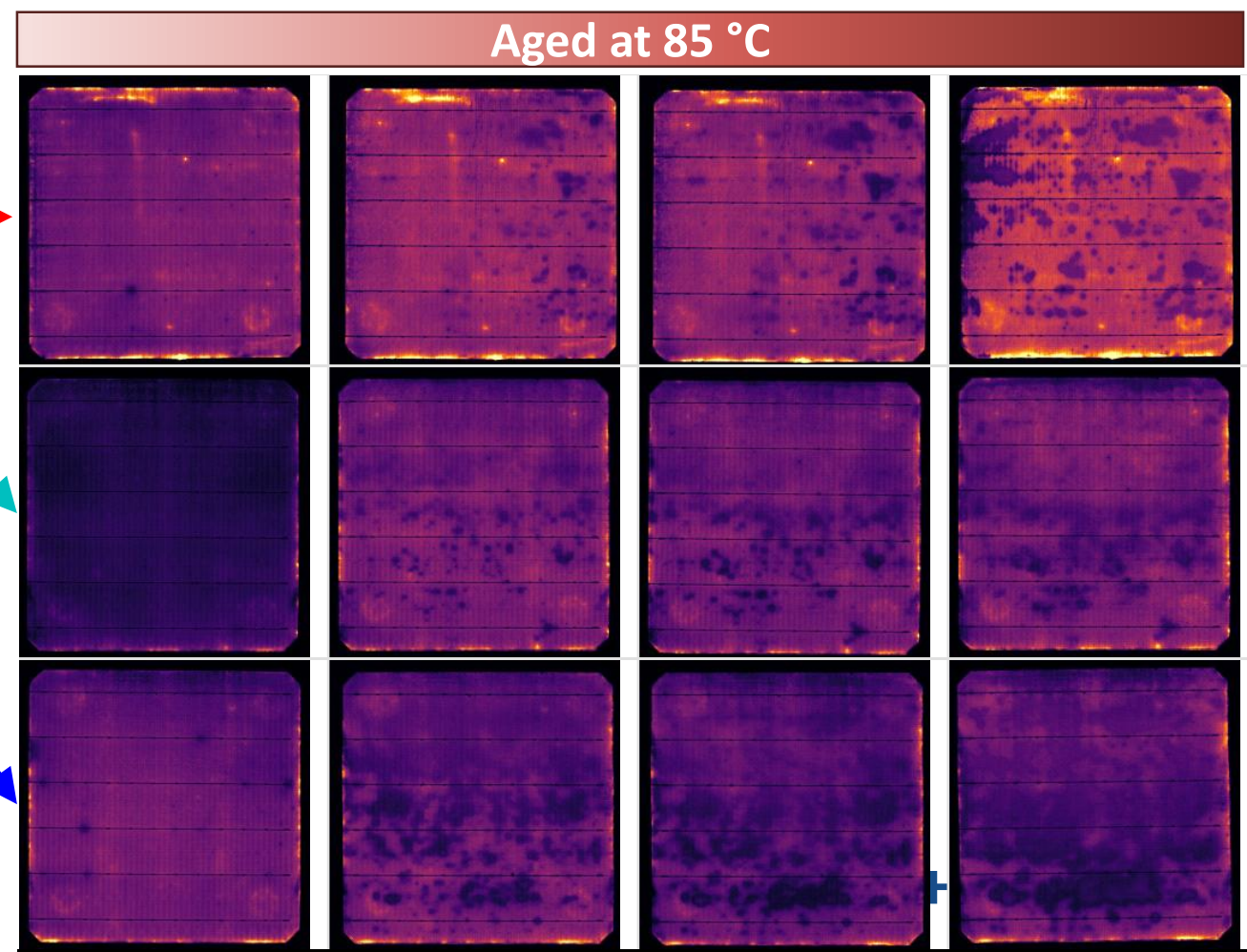
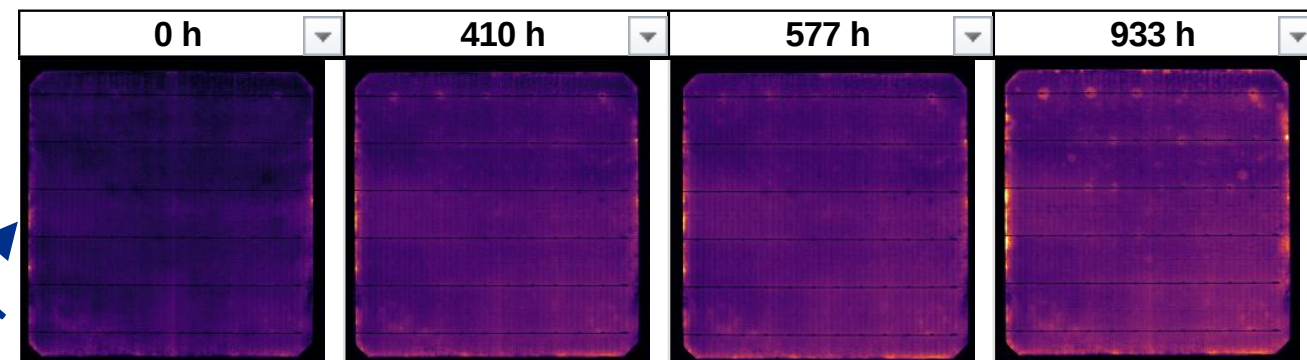
64826
48634
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16249
57

c-ITO, ref

IZO

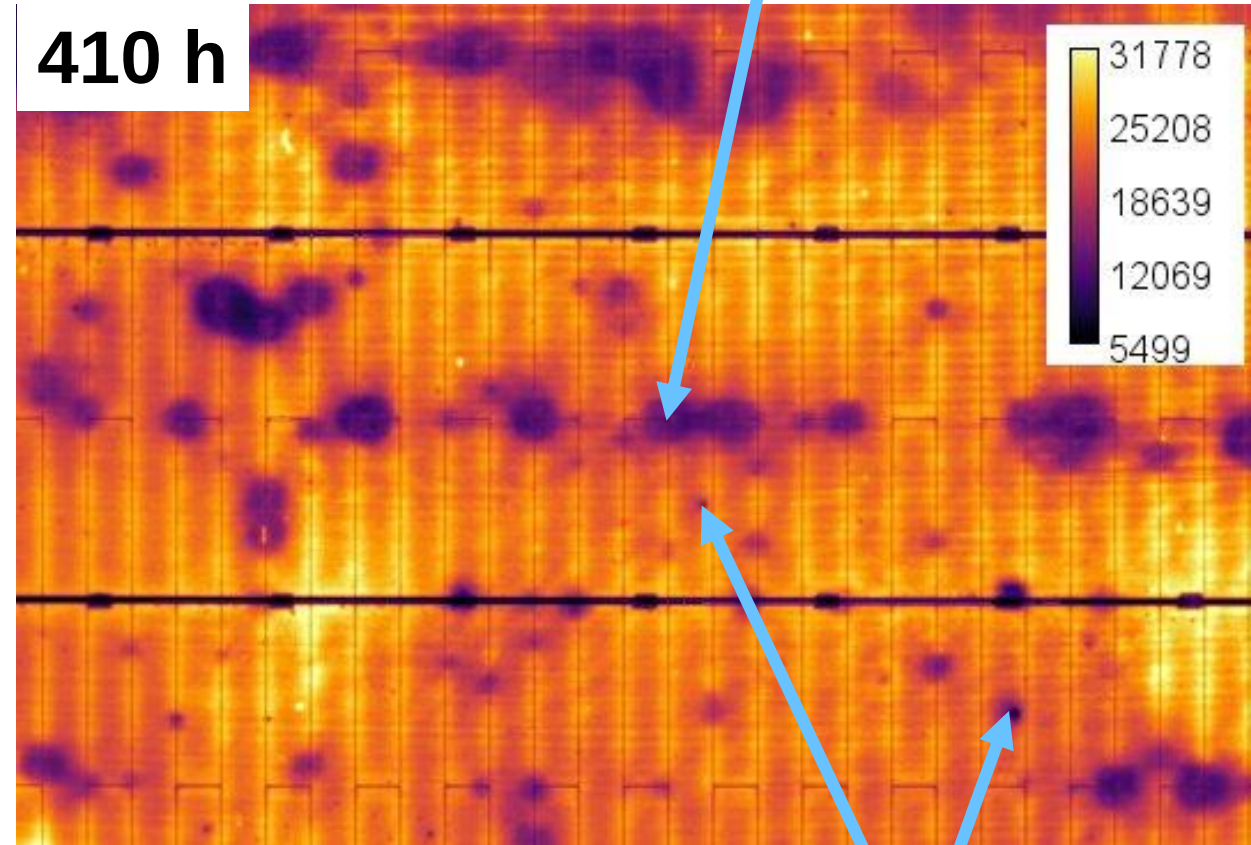
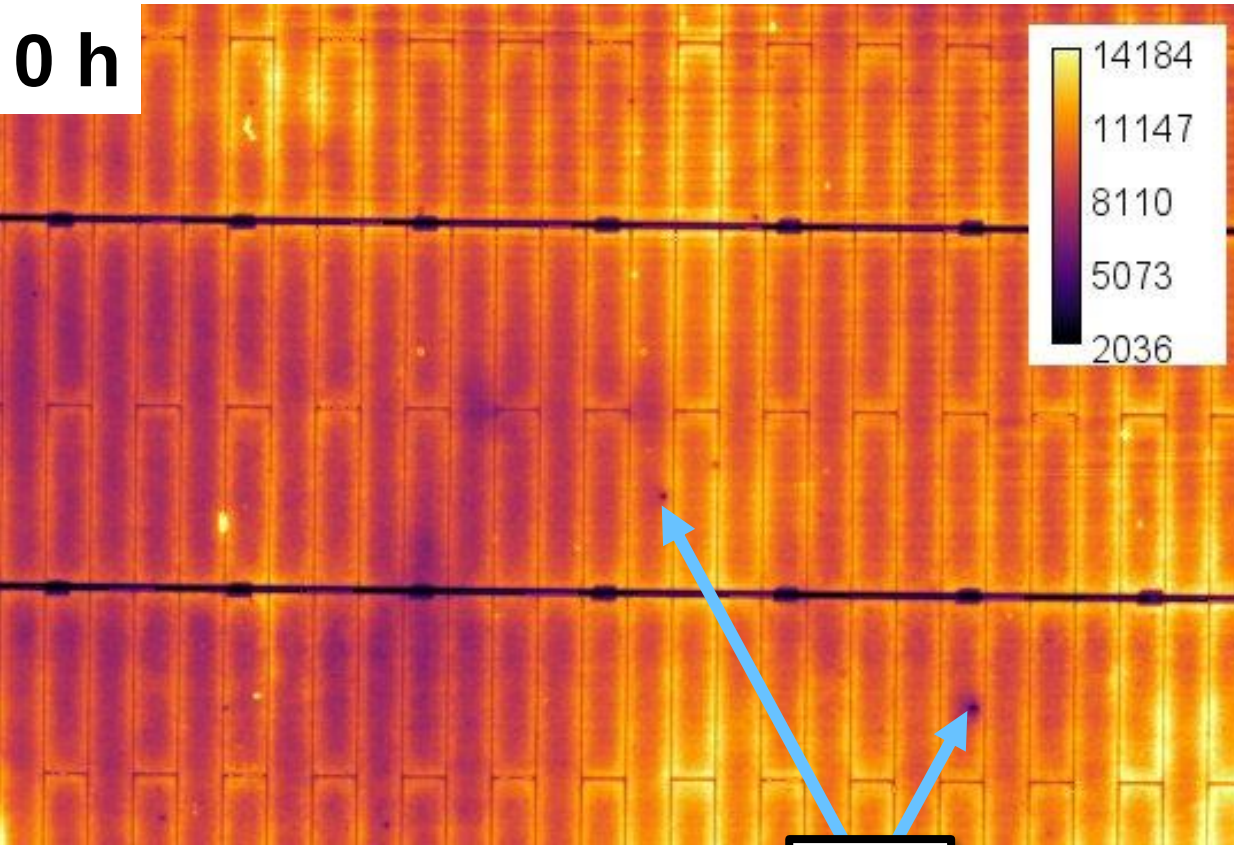
a-ITO

c-ITO



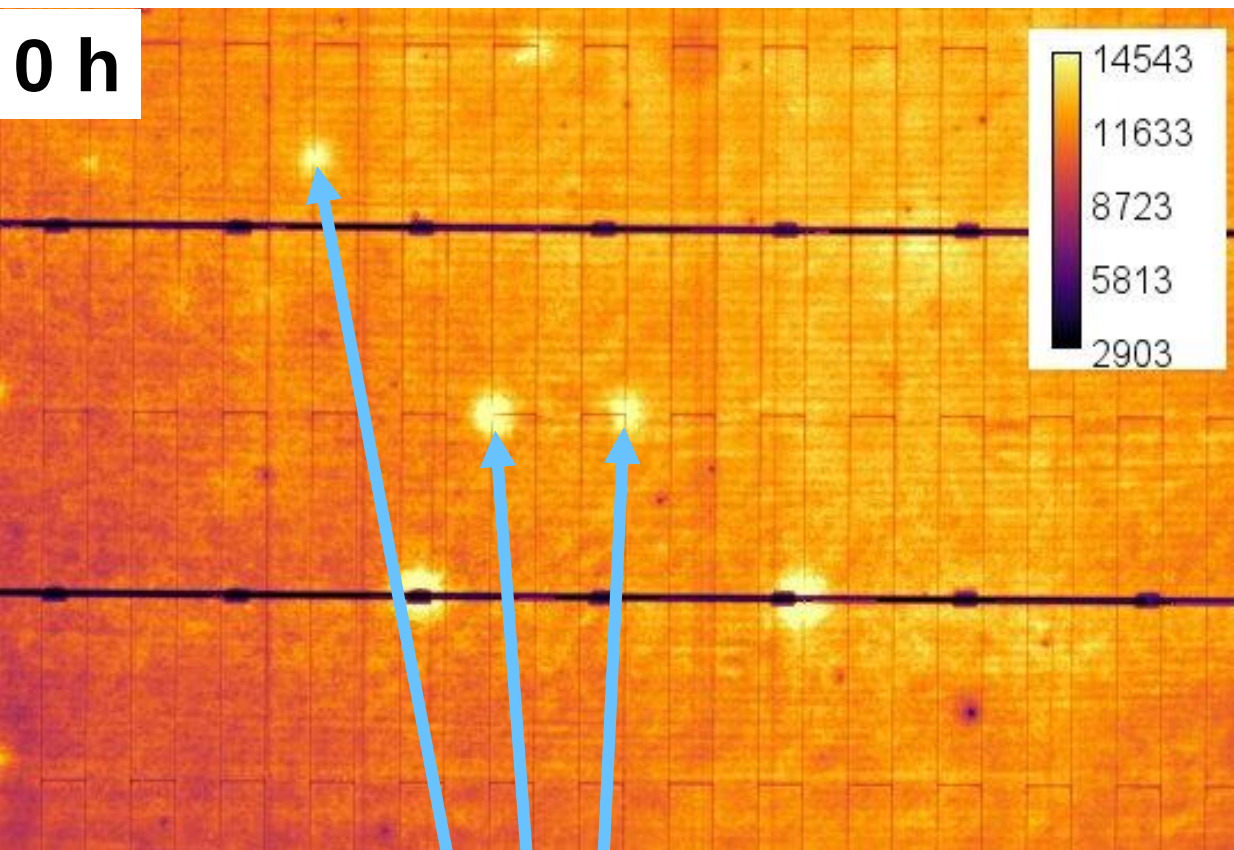
EL – CLOSER LOOK (a-ITO)

Aged at 85 °C, dark

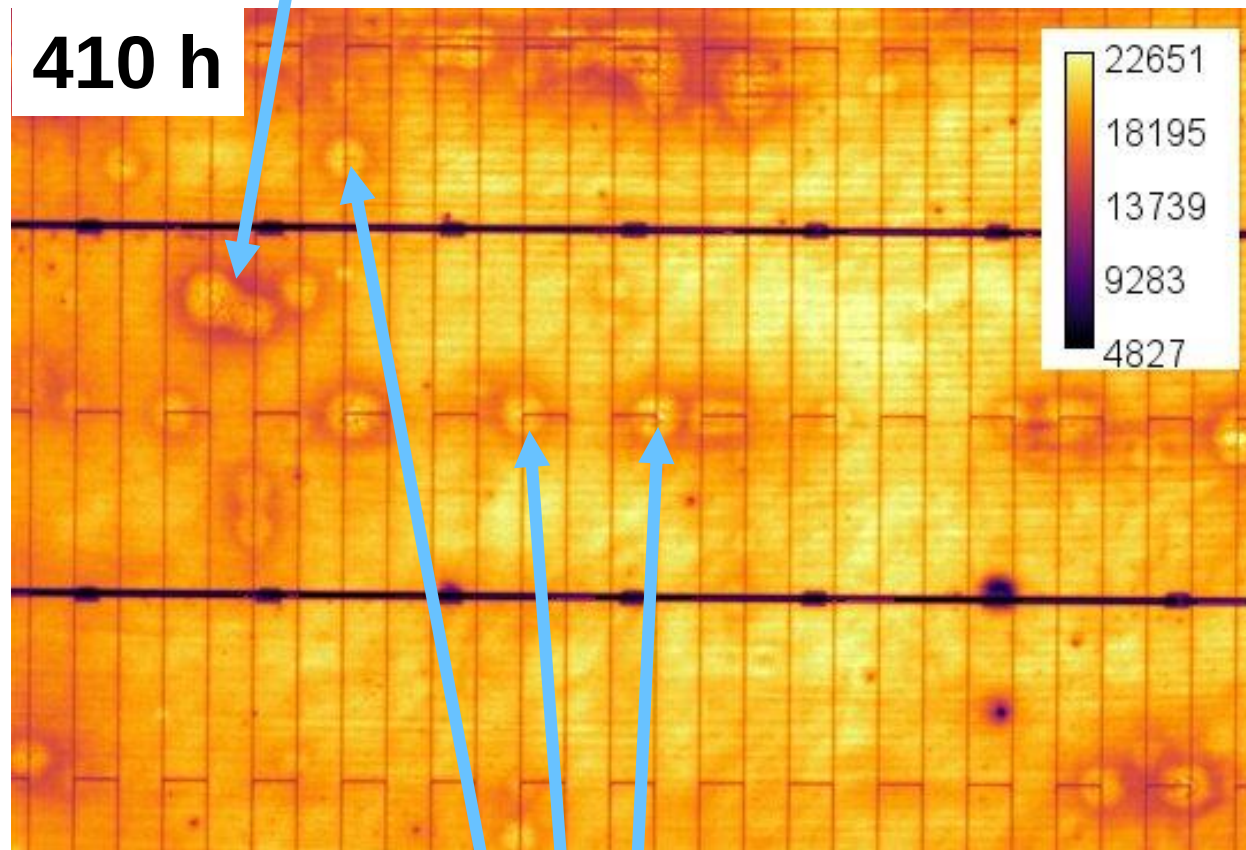


PL – CLOSER LOOK (a-ITO)

Aged at 85 °C, dark



Bright spots



Bright spots initiate degradation

Bright core surrounded by a dark ring, lines up with EL dark spots.

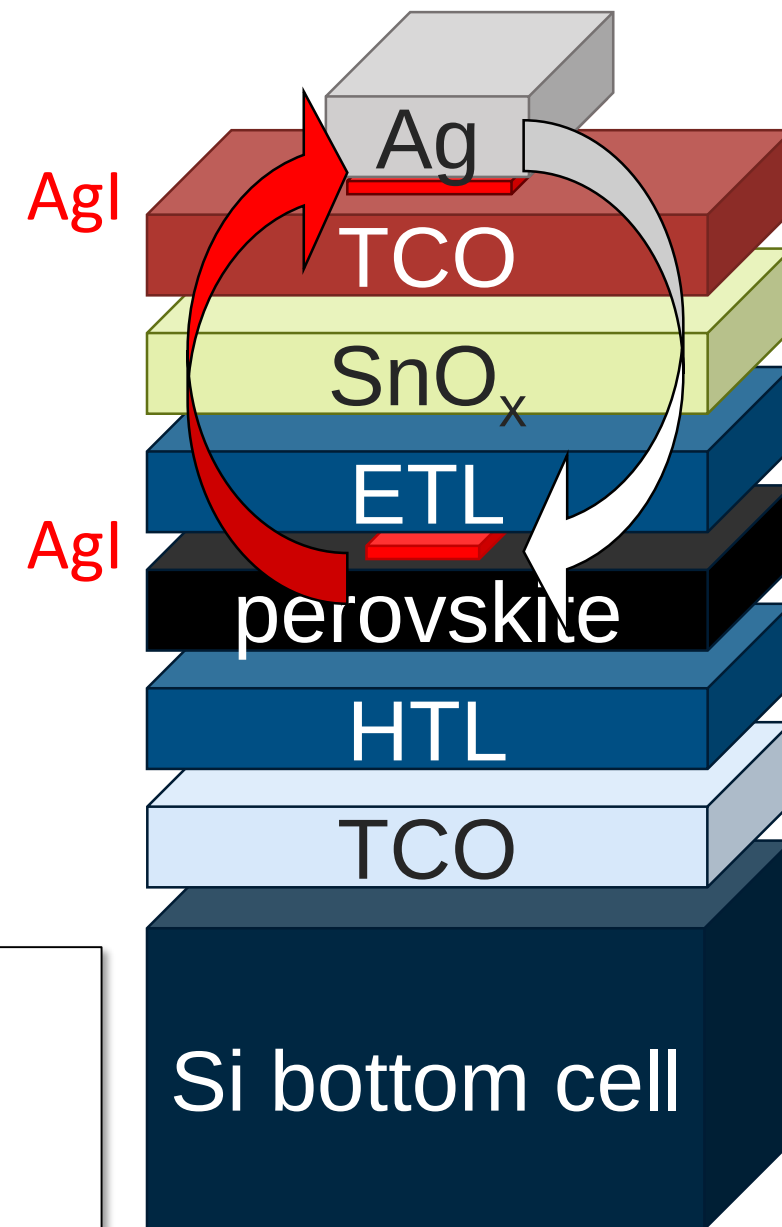
Degradation in charge transport layer, not perovskite.

CONCLUSIONS

- IZO > a-ITO > c-ITO
- All cells have PCE > 92 % after 933 h.
- Metal corrosion → drop in FF.
- Dark spots in EL + bright spots in PL → CTL damage.
- Dark EL spots always centred on Ag fingers: silver-related.

Outlook:

- Compare sp-Ag vs. evap-Ag vs. sp solvents.
- Compare sp-Ag to sp-Cu/Ag.
- Can Ag⁰ plating occur in tandems?



THANK YOU! 😊



- Co-authors.
- Oxford PV for tandem cells.
- Katja Mayer-Stillrich, Manuel Hartig and Denise Debrassine for TCO depositions.
- Dr. Guillermo Farias Basulto for SEM-EDX.
- Dr. Fengshuo Zu for XPS measurements.
- Dr. Philippe Holzhey for single-junction cells
- Dr. Arman Mahboubi Soufiani for ELI and P

SuperSolid

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